
MICRO-TRANSFER-PRINTING AND POTENTIAL PROCESS OPTIMIZATIONS BY FEA

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AGENDA

- Introduction
 - Motivation
 - MICROPRINCE-Project
 - Micro-Transfer-Printing
- Mechanical Characterization
 - Viscoelastic Properties
 - Adhesion Measurements
- Finite-Element-Analysis
 - Numerical Validation
 - μ TP-Process Simulation
- Summary
- Outlook

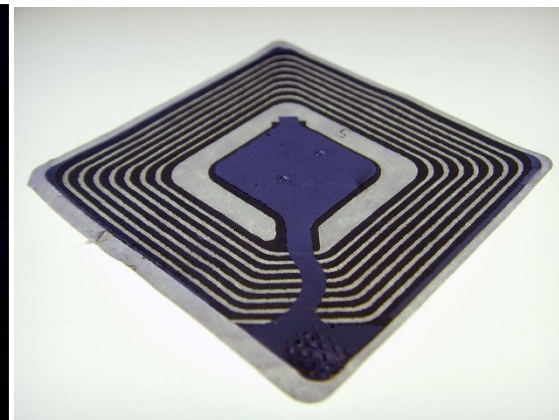
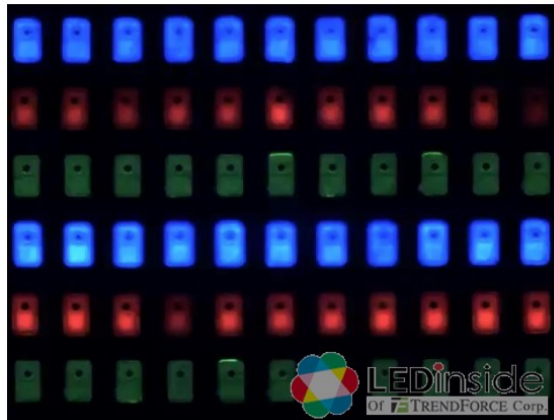
Introduction

Motivation

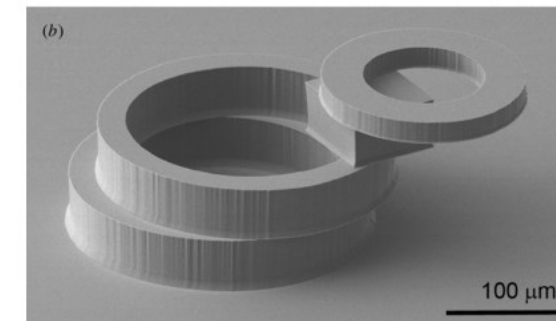
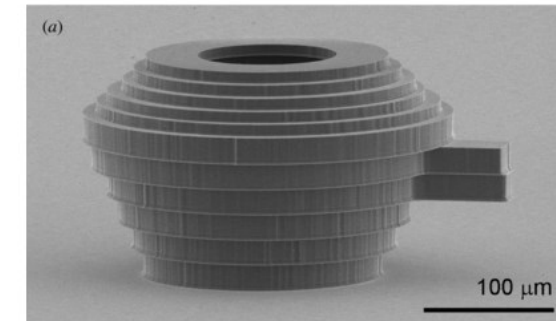
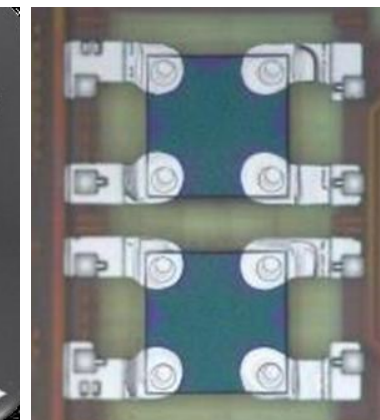
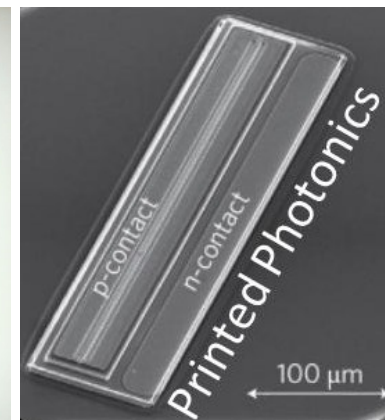
- Rising demand on electronic components
 - μ LEDs, MEMS, RFID chips, printed photonics
- Advanced packaging technologies required
 - for handling of thin, fragile and small devices
 - Combining components of various materials
 - Components from wafers with different diameter (2", 3", 4" ...)



<https://www.osram.com/am/light-for/led-lighting/led-interior-lighting-ledambient/index.jsp>



https://commons.wikimedia.org/wiki/File:RFID_Chip_004.JPG

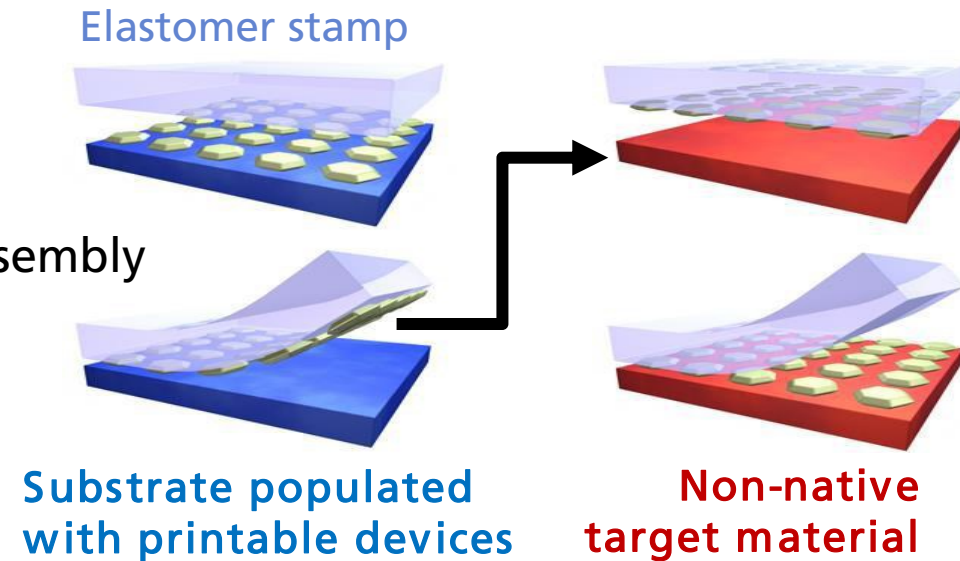


Hohyun Keum et al 2012 J. Micromech. Microeng. 22 055018

Introduction

Motivation

- Micro-Transfer-Printing (μ TP) versatile technology for micro-assembly (pick and place)



- Parallel transfer of microscale functional components from a native substrate to a non-native target material via an elastomer stamp

→ MICROPRINCE project

creating the worldwide first open access **pilot line for heterogeneous integration** of smart systems by **micro-transfer-printing (μ TP)** in a semiconductor foundry manufacturing environment

Introduction

MICROPRINCE-Project



- 1) Transfer of the μ TP from research to an industrial environment
- 2) Creation, installation and demonstration of a μ TP pilot line in a semiconductor foundry manufacturing environment
- 3) Demonstration on defined target applications
(Hall plates for current sensors; filter for optical sensors; μ LEDs for car ambient lighting; LEDs, sensors and modulators for Si-photonics applications)
- 4) Development of μ TP as platform technology including design rules and their implementation in Process Design Kits (PDK)



Introduction

MICROPRINCE-Project

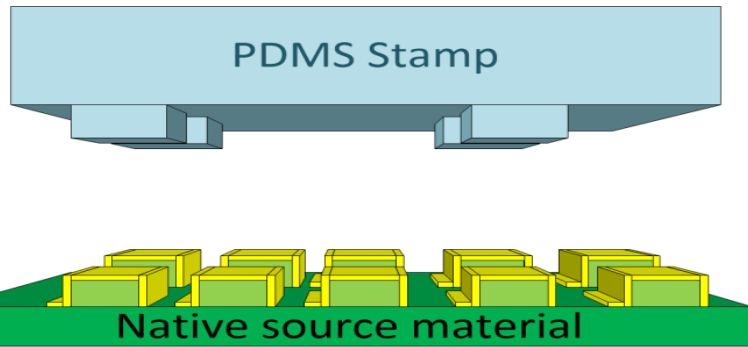


- 1) Transfer of the μ TP from research to an industrial environment
- 2) Creation, installation and demonstration of a μ TP pilot line in a semiconductor foundry manufacturing environment

Introduction

Micro-Transfer-Printing

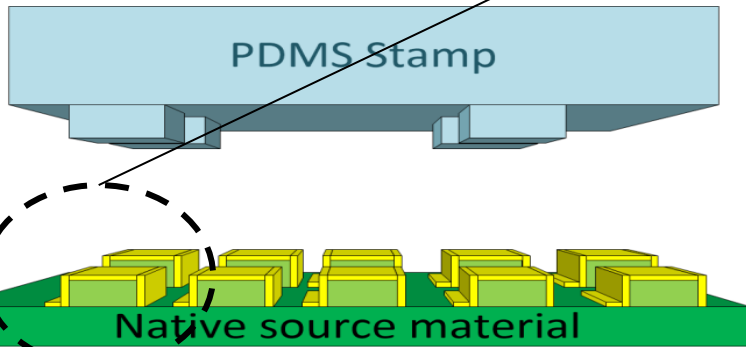
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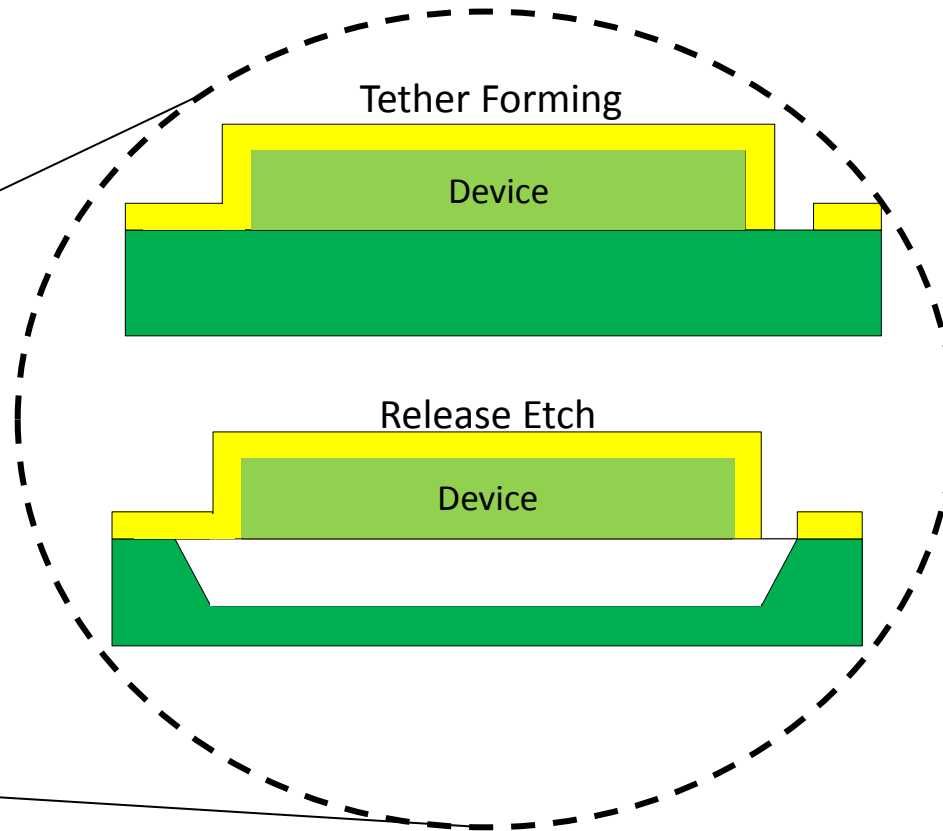
Introduction

Micro-Transfer-Printing

1)



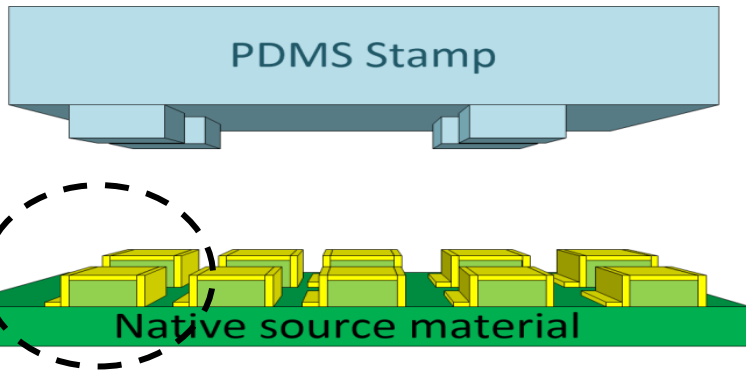
1) Release devices from source material



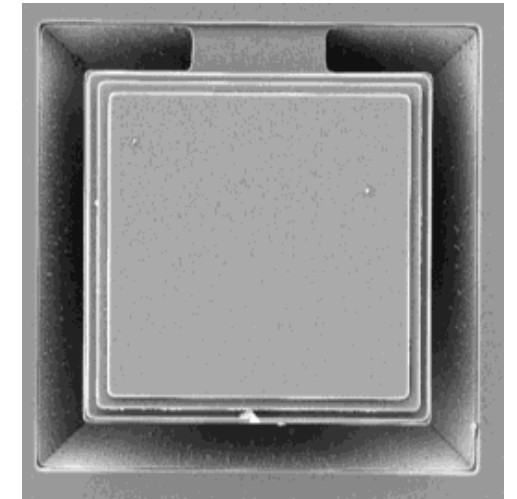
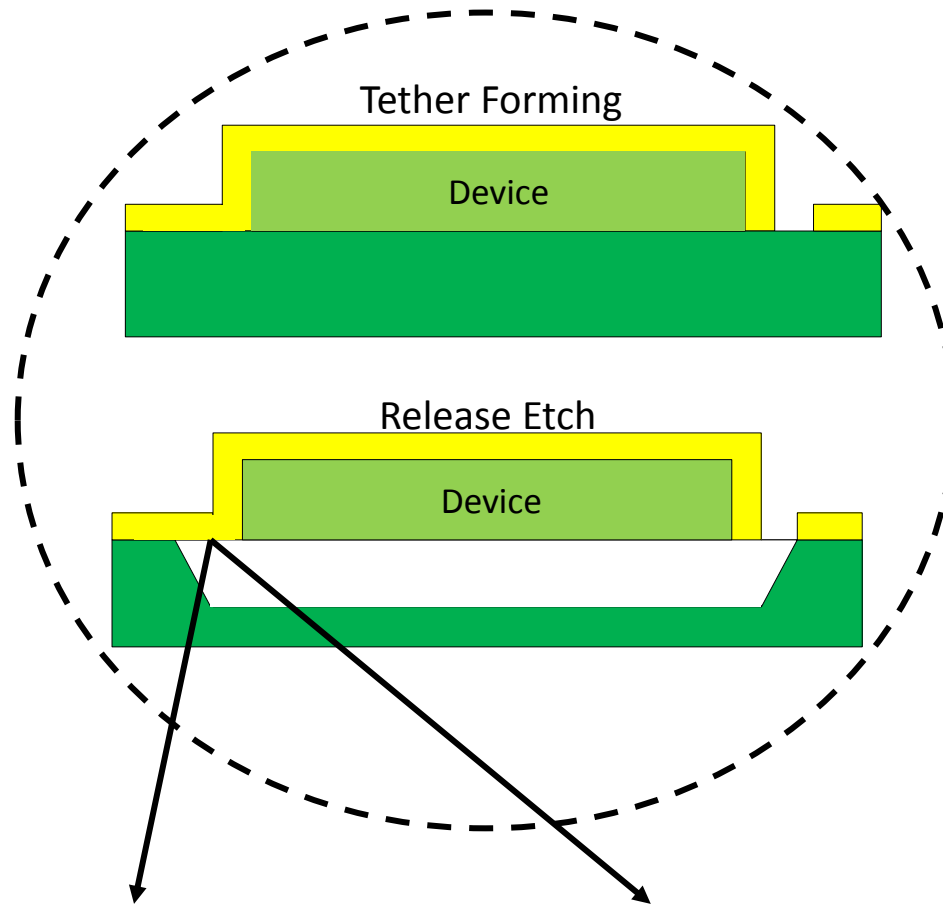
Introduction

Micro-Transfer-Printing

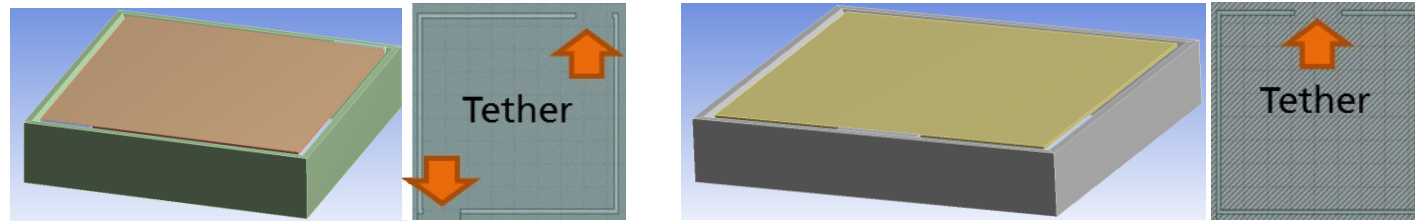
1)



1) Release devices from source material



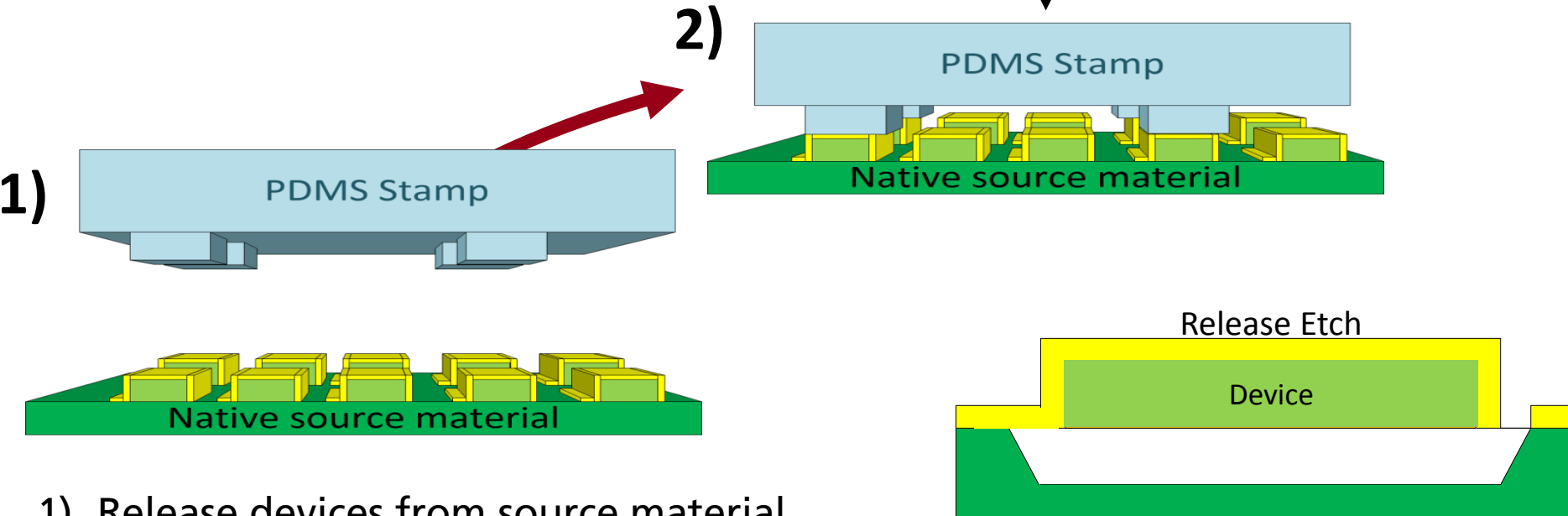
Top view of device held by tether (SEM)



Different potential tether designs

Introduction

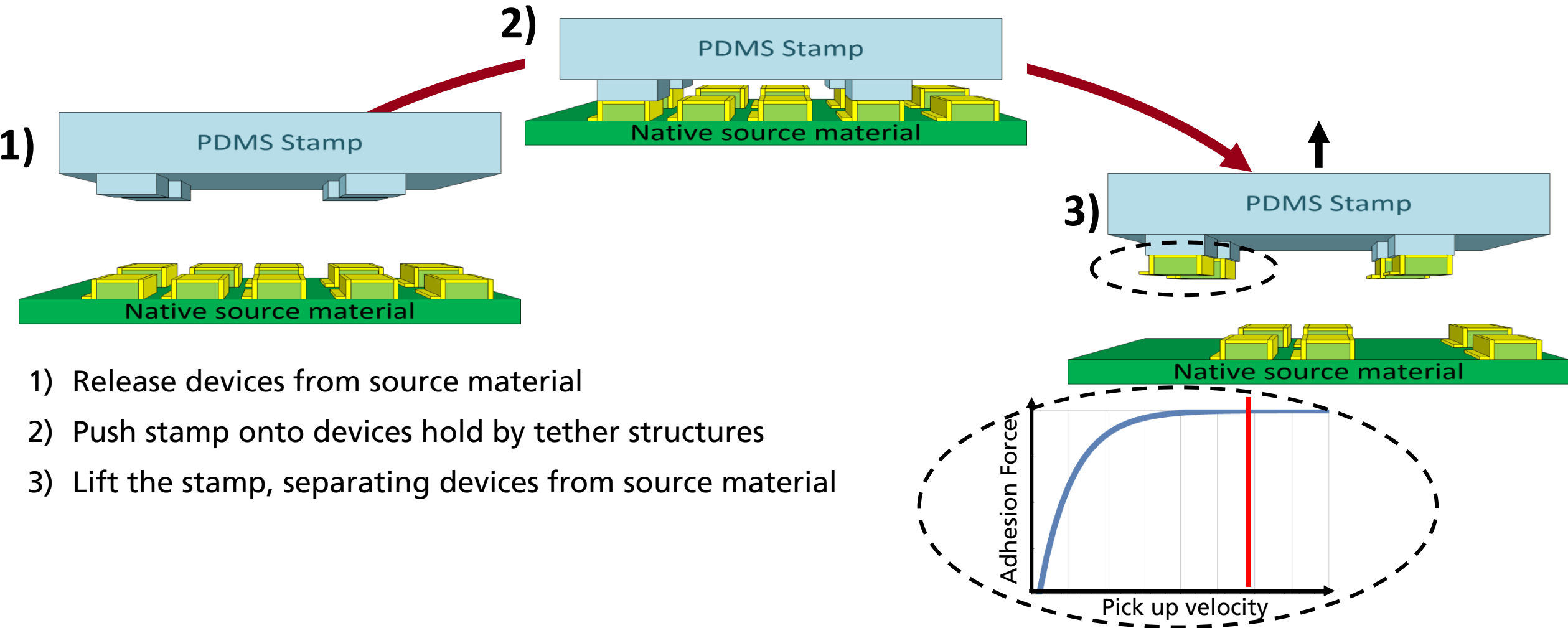
Micro-Transfer-Printing



- 1) Release devices from source material
- 2) Pushing stamp onto devices hold by tether structures

Introduction

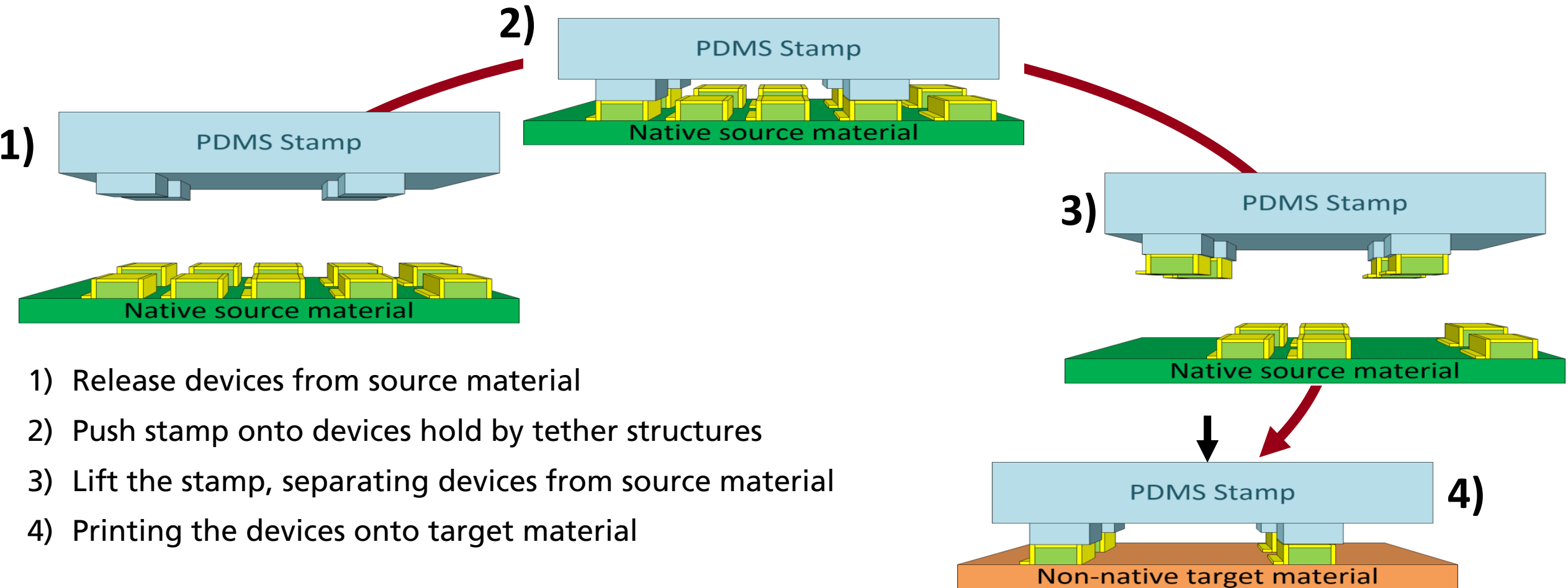
Micro-Transfer-Printing



- 1) Release devices from source material
- 2) Push stamp onto devices hold by tether structures
- 3) Lift the stamp, separating devices from source material

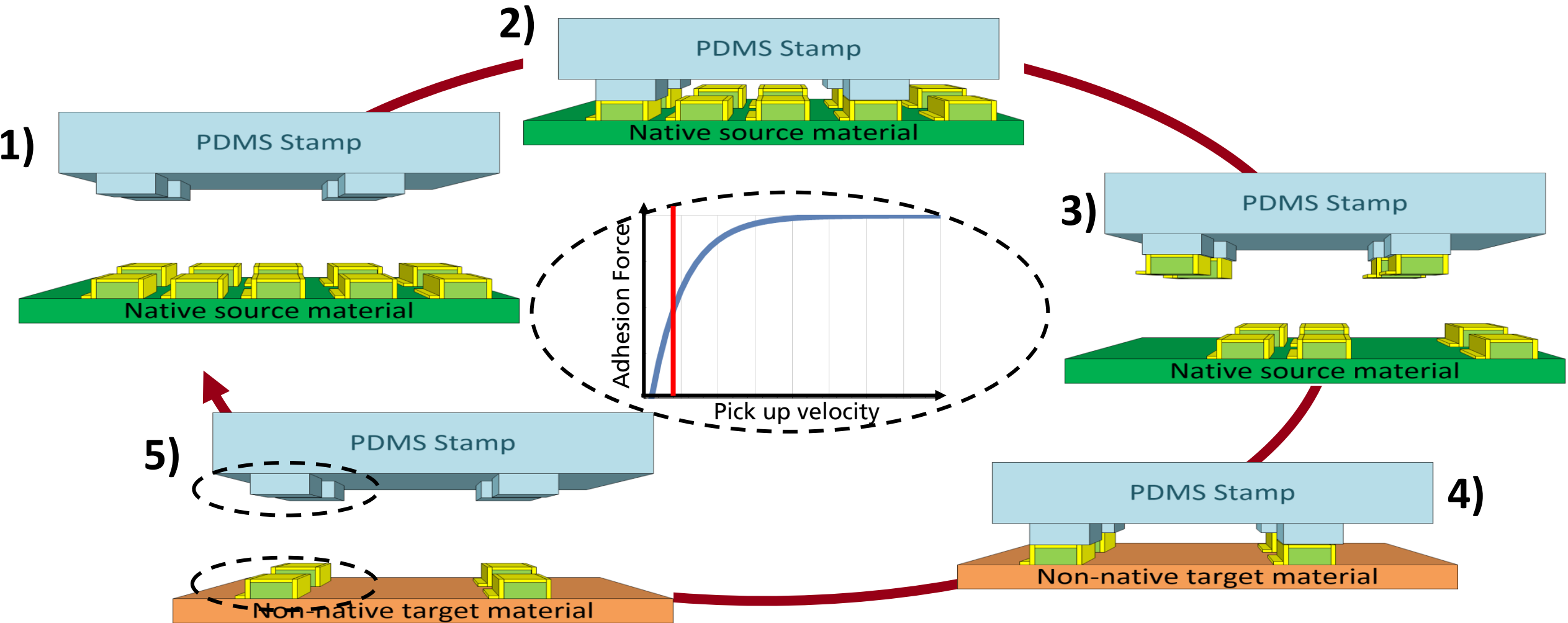
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Micro-Transfer-Printing



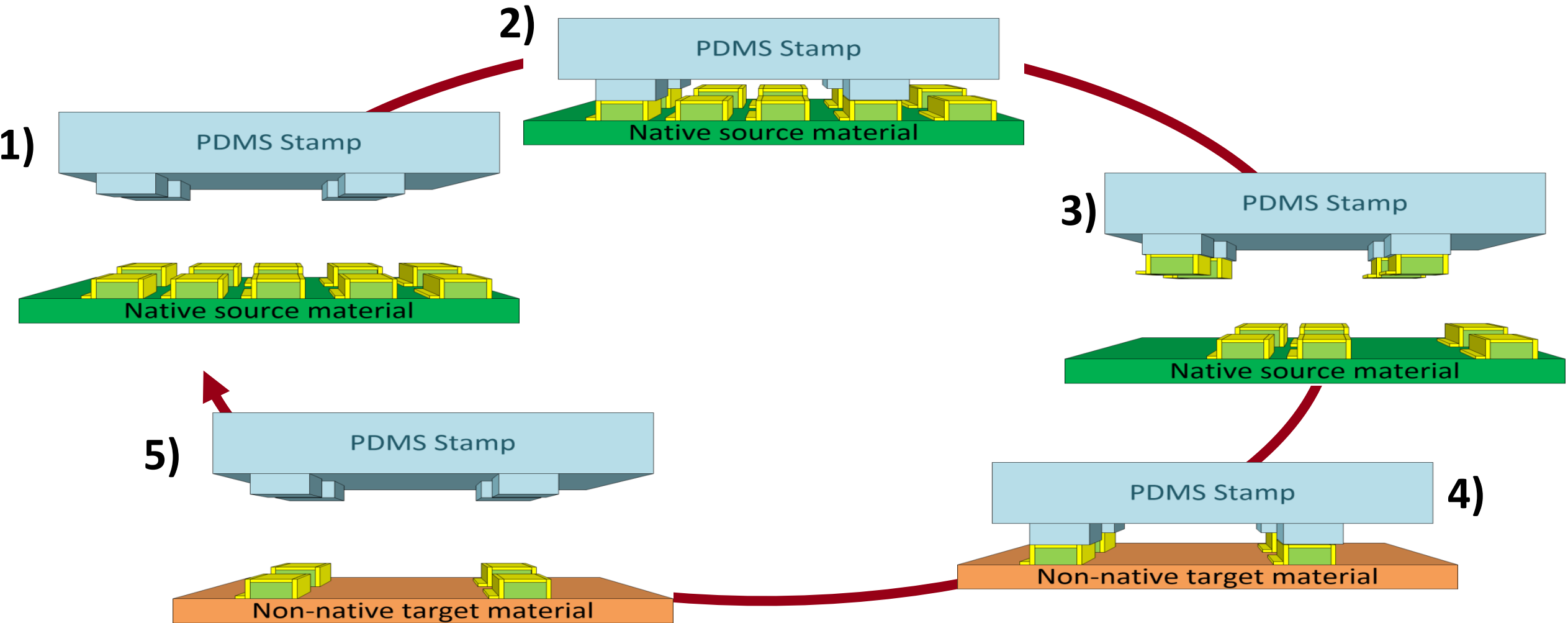
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Micro-Transfer-Printing



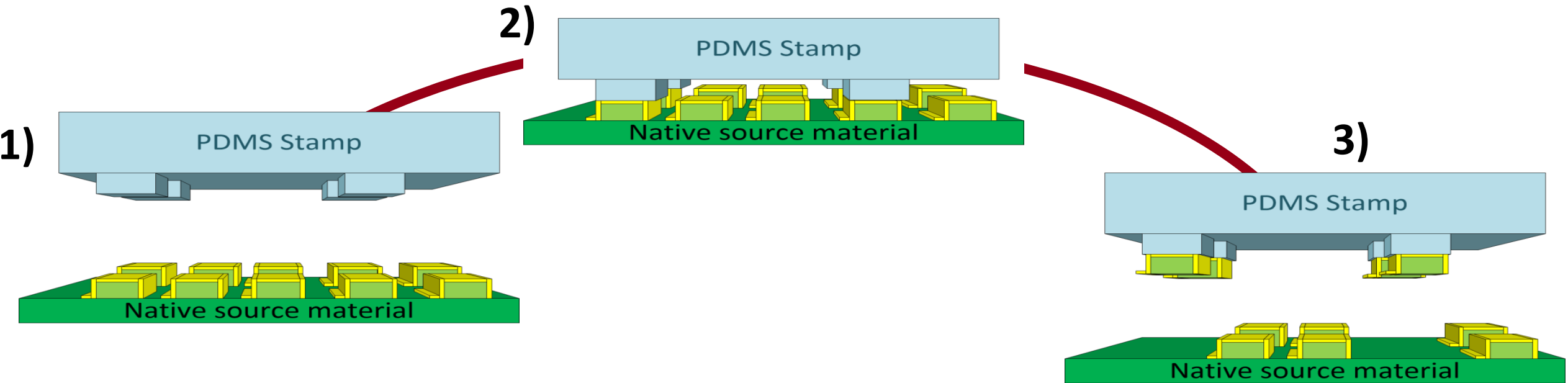
Introduction

Micro-Transfer-Printing



Introduction

Micro-Transfer-Printing



Simulation is dealing with the pick up stage

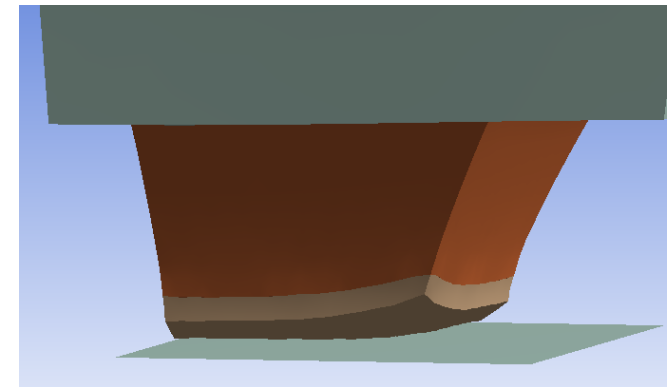
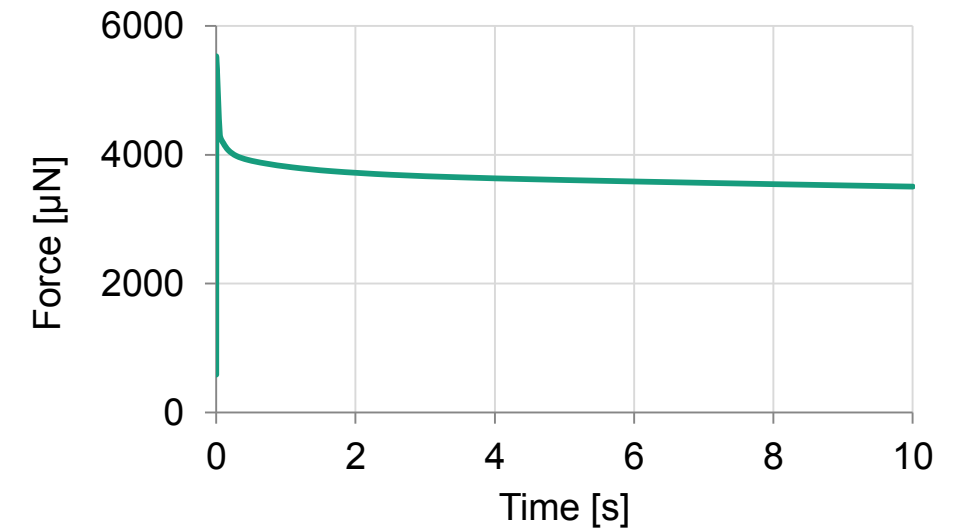
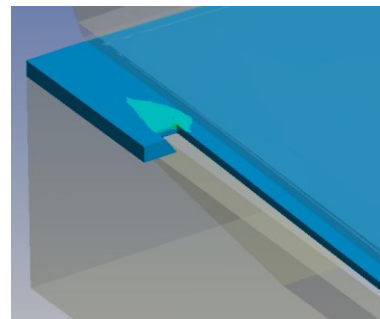
Micro-Transfer-Printing

Challenges and Goals for μ TP-Simulation

- PDMS stamp material behaviour
 - Viscoelasticity

- Adhesion of the stamp on chiplet surface
 - Rate dependent

- Stress of tether structure

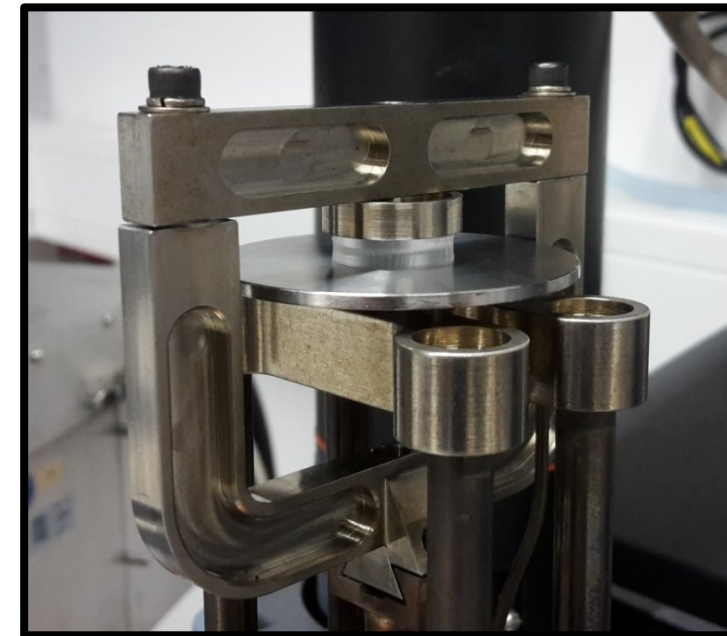
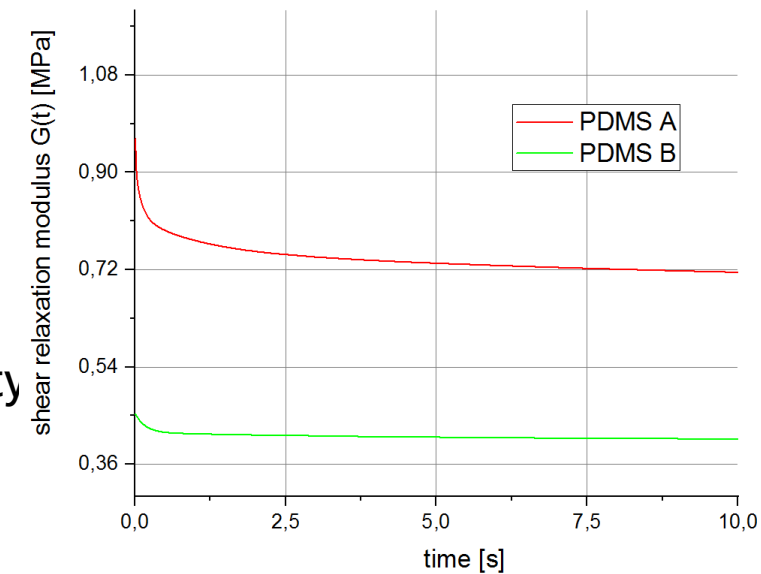


Mechanical characterization

Viscoelastic properties

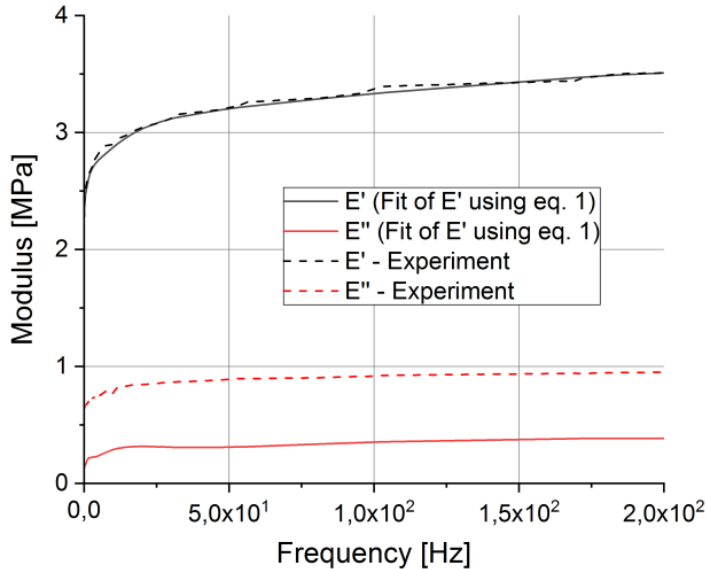
- Elastomer stamp material shows highly nonlinear behavior (viscoelasticity)
 - Wide range of material data in literature
 - Depending on manufacturing conditions and the way of loading

- Performing dynamic sweep measurements in compression mode
 - DMA TA Q800
 - Cylindrical PDMS specimen (d=13mm, t=3.1mm)
 - Temperature range of -50...150°C, frequency range of 1...55 Hz (TTS)



Mechanical characterization

Viscoelastic properties



Generalized Maxwell model [1]

$$E' = \sum_{i=1}^Z \frac{E_i \omega^2 \tau_i^2}{1 + \omega^2 \tau_i^2} \quad (1)$$

$$E'' = \sum_{i=1}^Z \frac{E_i \omega \tau_i}{1 + \omega^2 \tau_i^2} \quad (2)$$

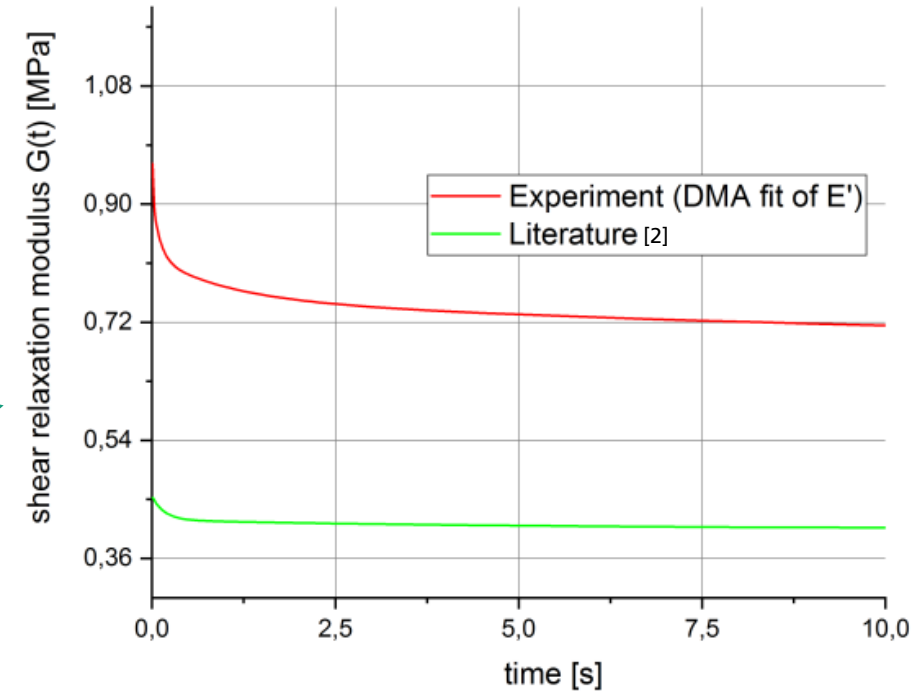
$$\omega = 2 \cdot \pi \cdot f$$

$$E(t) = 2 \cdot G(t) \cdot (1 + \nu) = \sum_{i=1}^Z E_i \cdot e^{-t/\tau_i} \quad (3)$$

E' – storage modulus

E'' – loss modulus

$\nu=0.49$



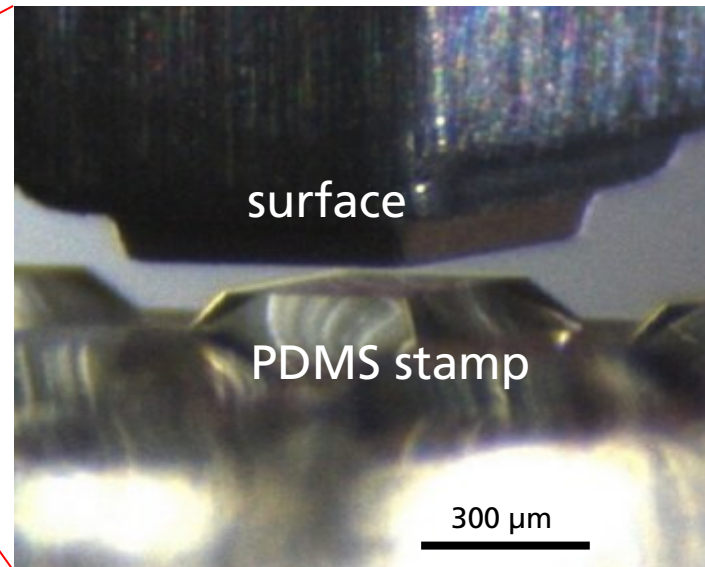
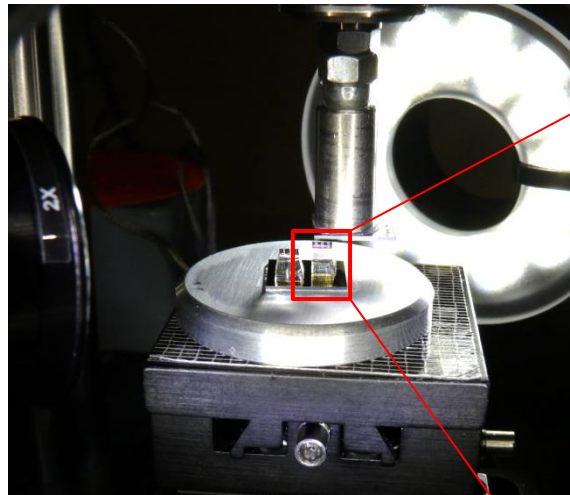
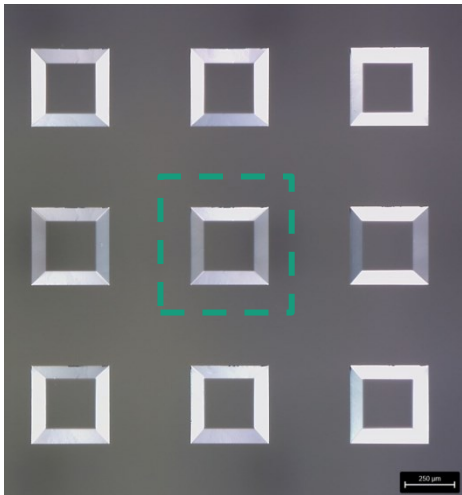
■ TTS data fit by equation (1)

➔ Time dependent shear relaxation modulus for viscoelastic data in ANSYS (Prony fit)

Mechanical characterization

Adhesion measurements

- Single PDMS-post on Si_3N_4 surface

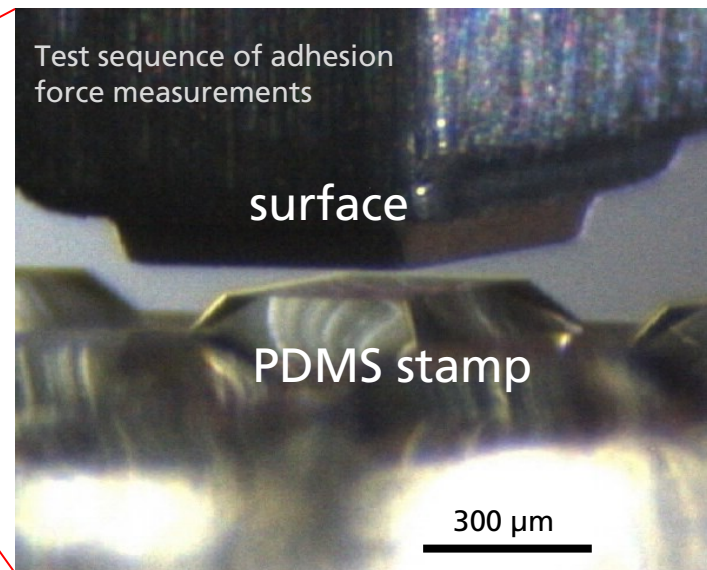
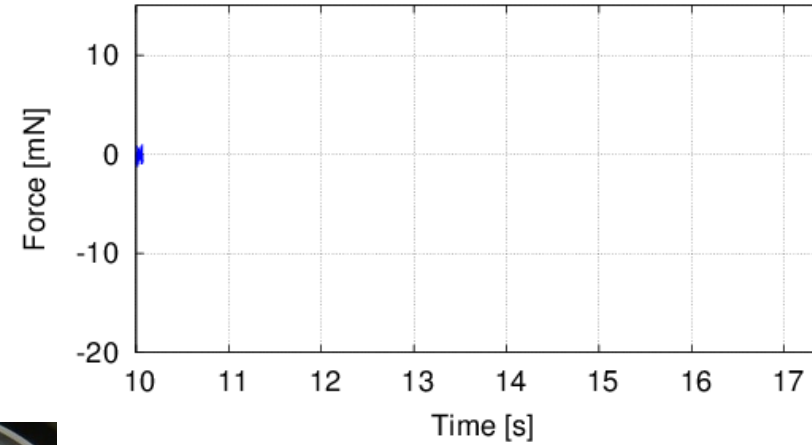
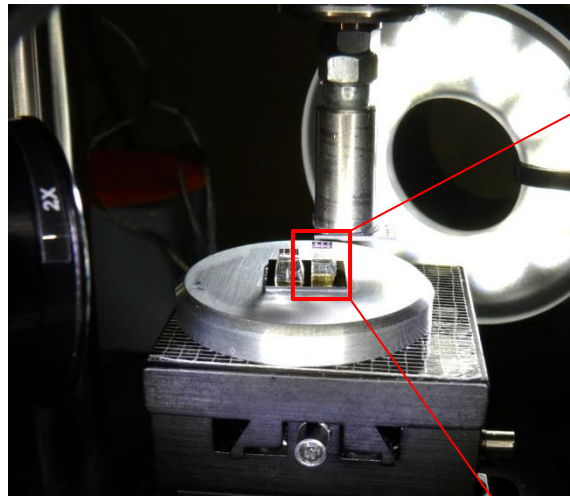
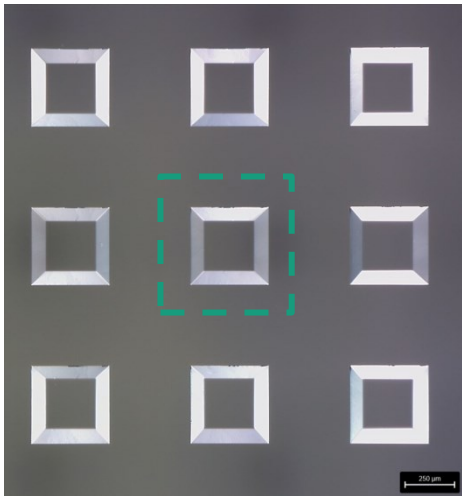


- Pick-up velocities of 1...132 mm/s
- Overdrive force 11mN
- 5 single posts of a PDMS array were tested

Mechanical characterization

Adhesion measurements

- Single PDMS-post on Si_3N_4 surface

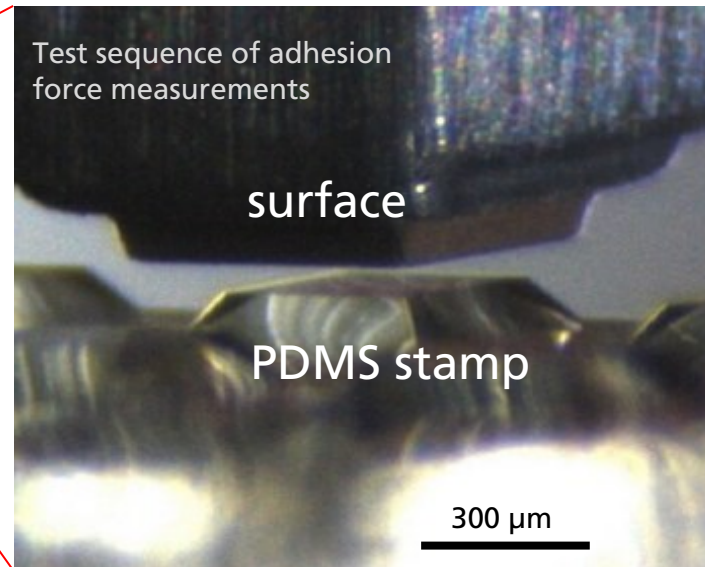
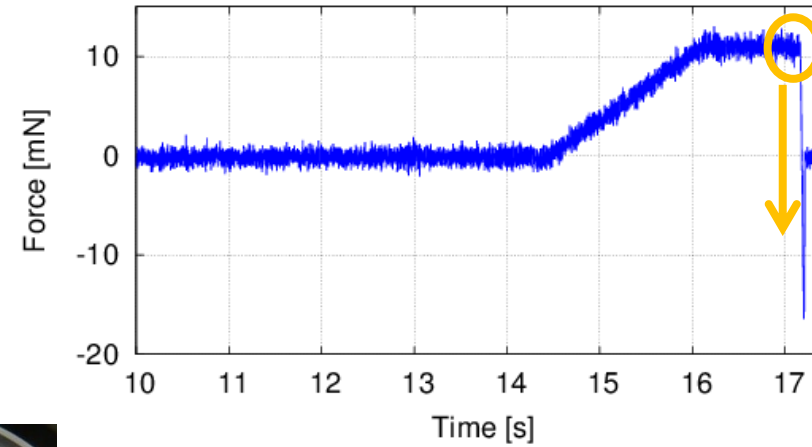
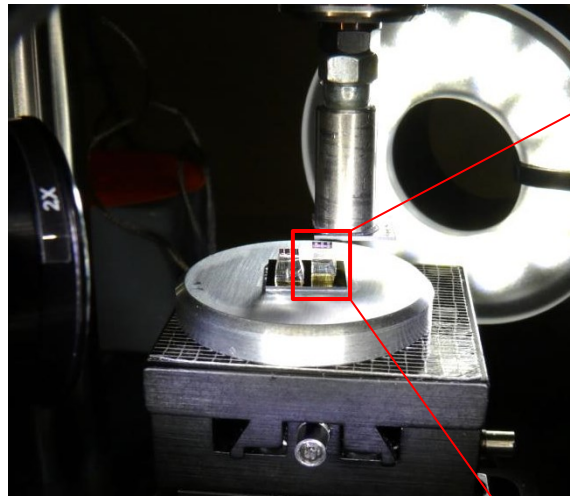
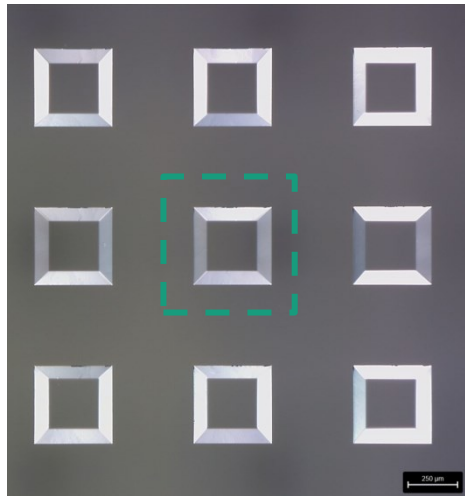


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Mechanical characterization

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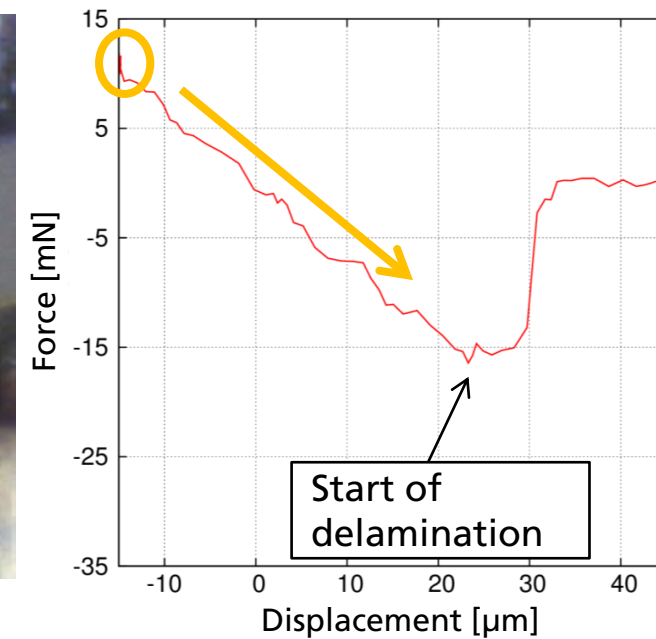
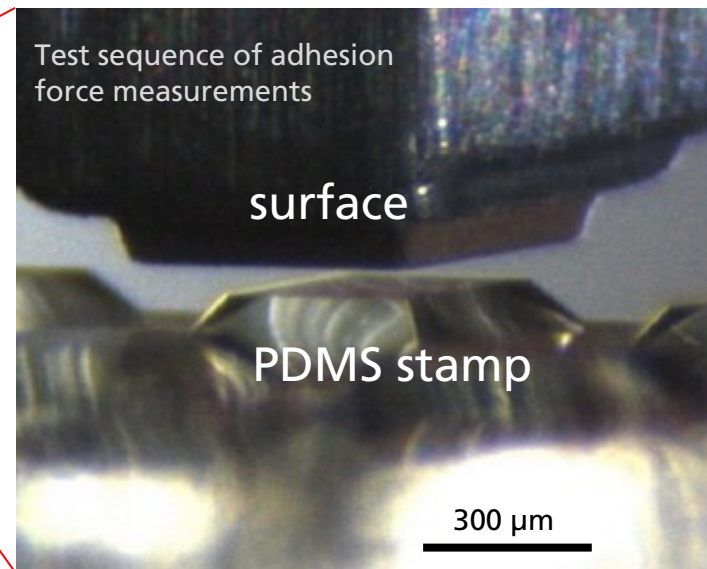
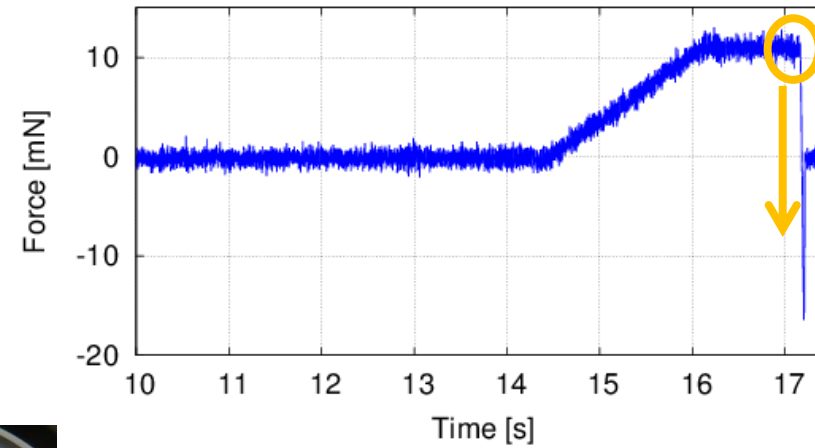
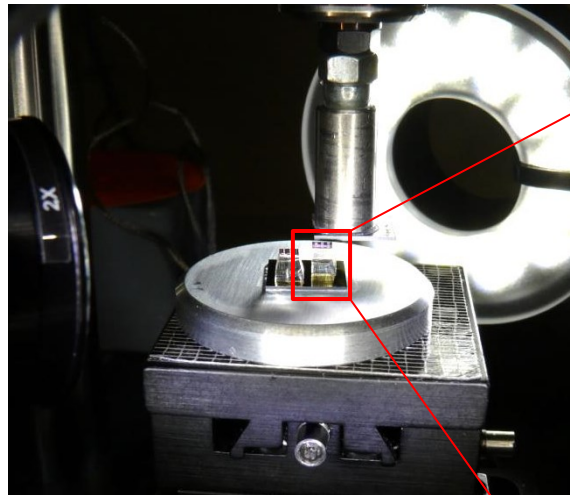
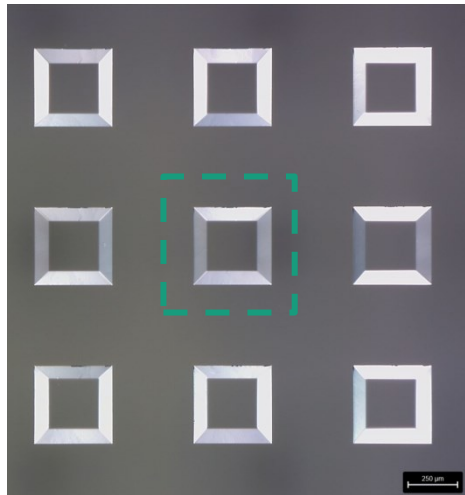


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Mechanical characterization

Adhesion measurements

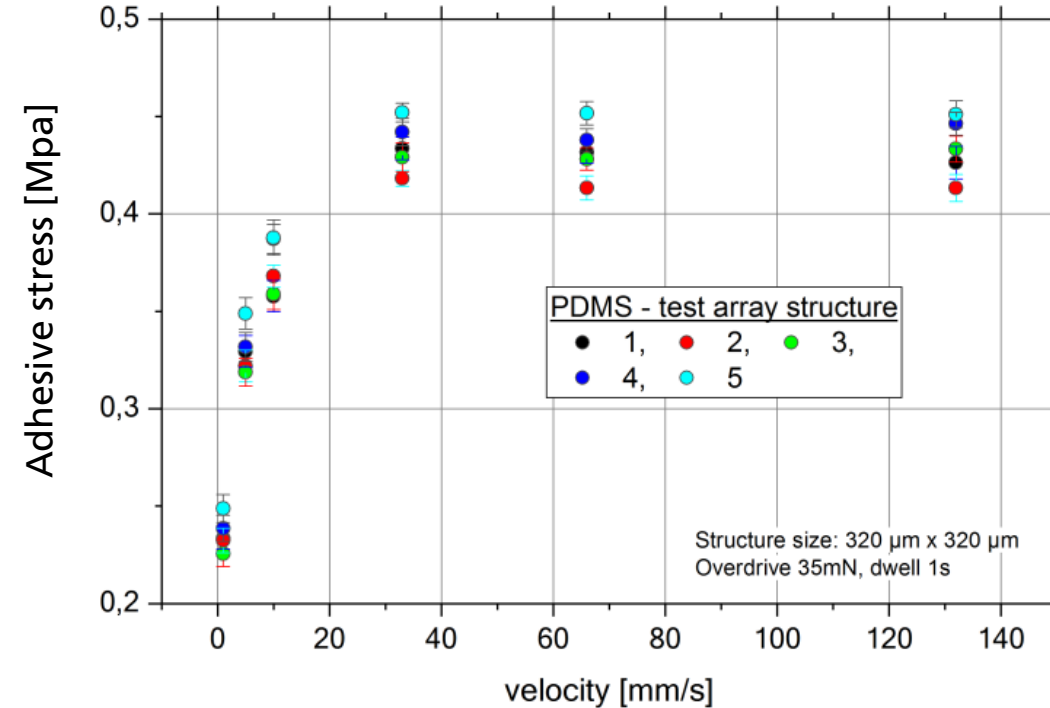
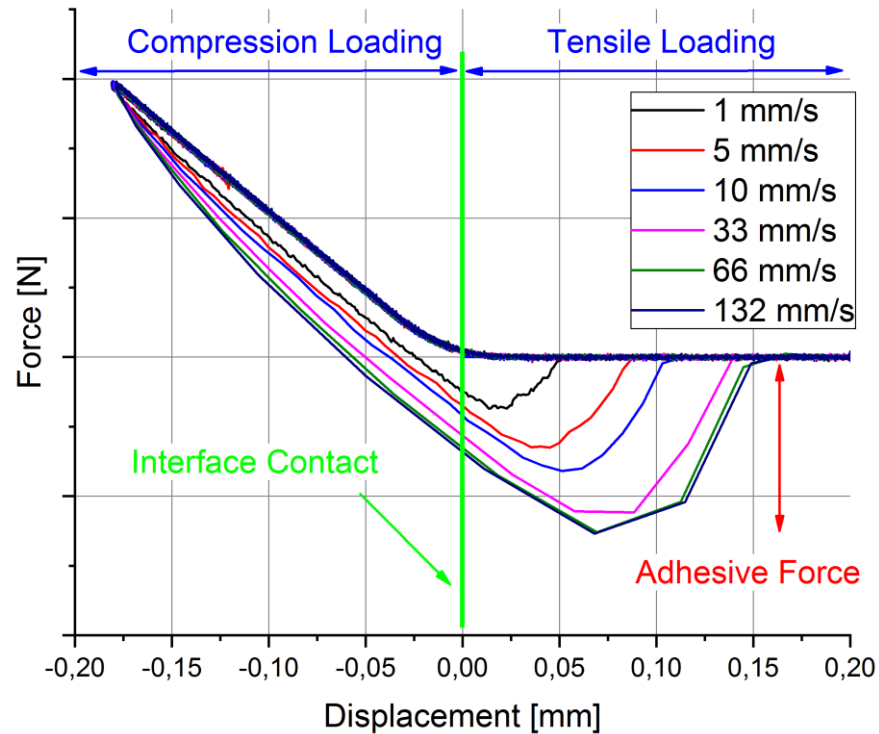
- Single PDMS-post on Si_3N_4 surface



- Pick-up velocities of 1...132 mm/s
- Overdrive force 11mN
- 5 single posts of a PDMS array were tested

Mechanical characterization

Adhesion measurements



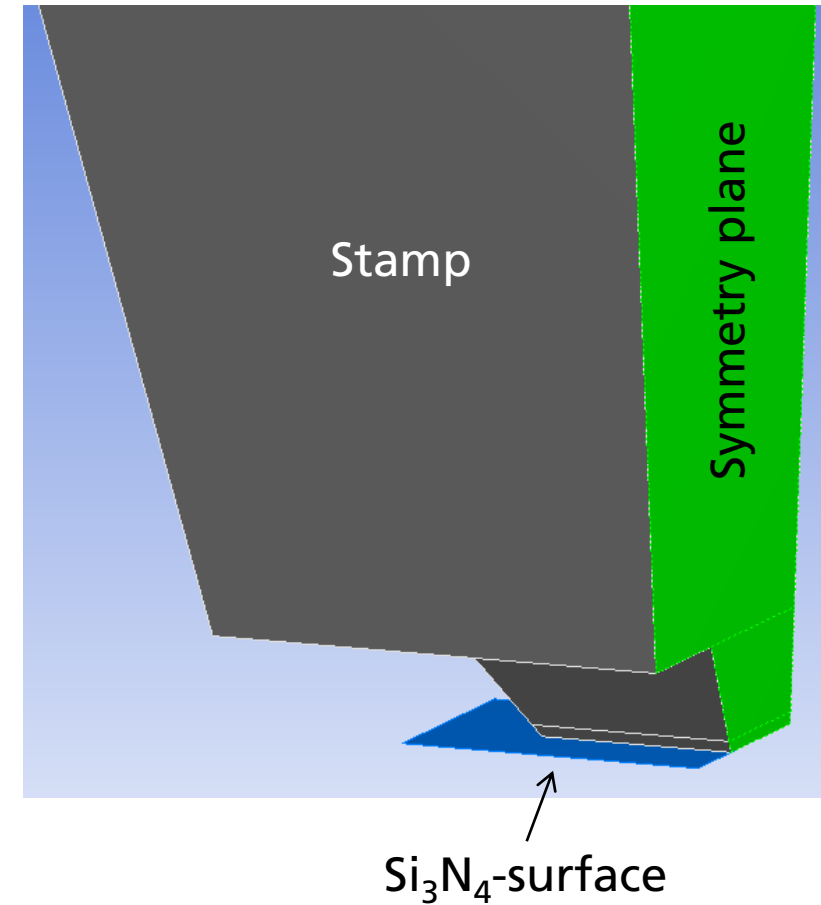
- Adhesion force and displacement strongly dependent on pick-up velocity
- Low scattering of different posts
- Maximum adhesion stresses using velocities greater 33mm/s

Finite-element-analysis

Numerical Validation

Model Setup

- Single post of a stamp array, using Quarter symmetry
- PDMS stamp → viscoelastic material model
- Si_3N_4 -surface → rigid target

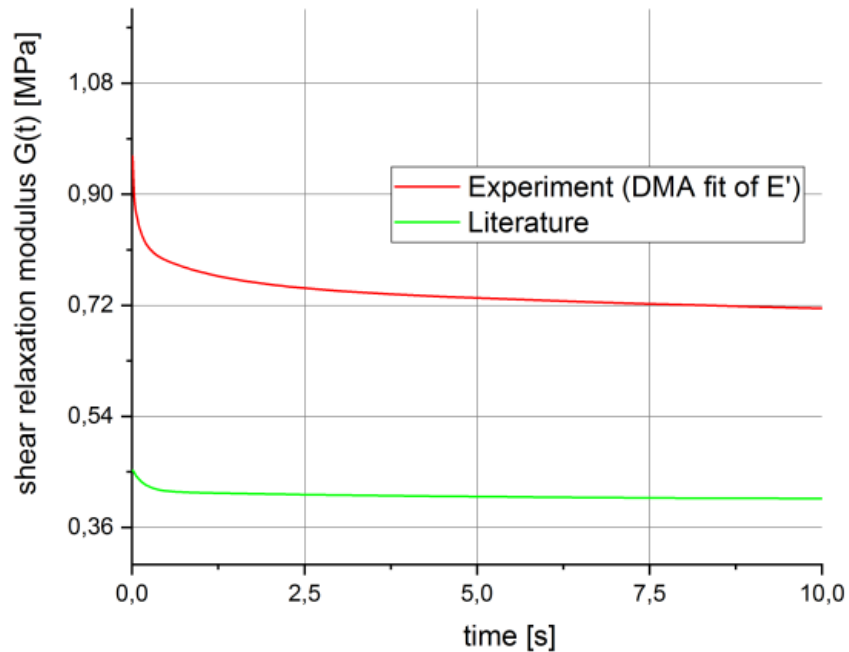
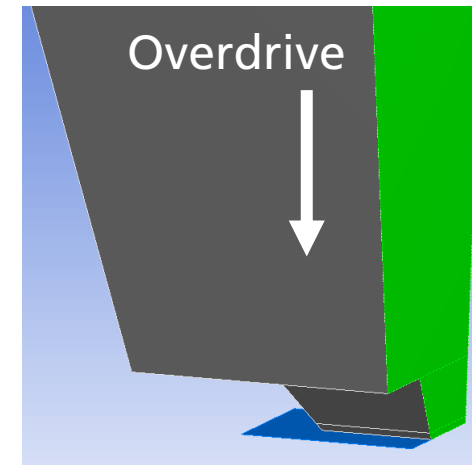


Finite-element-analysis

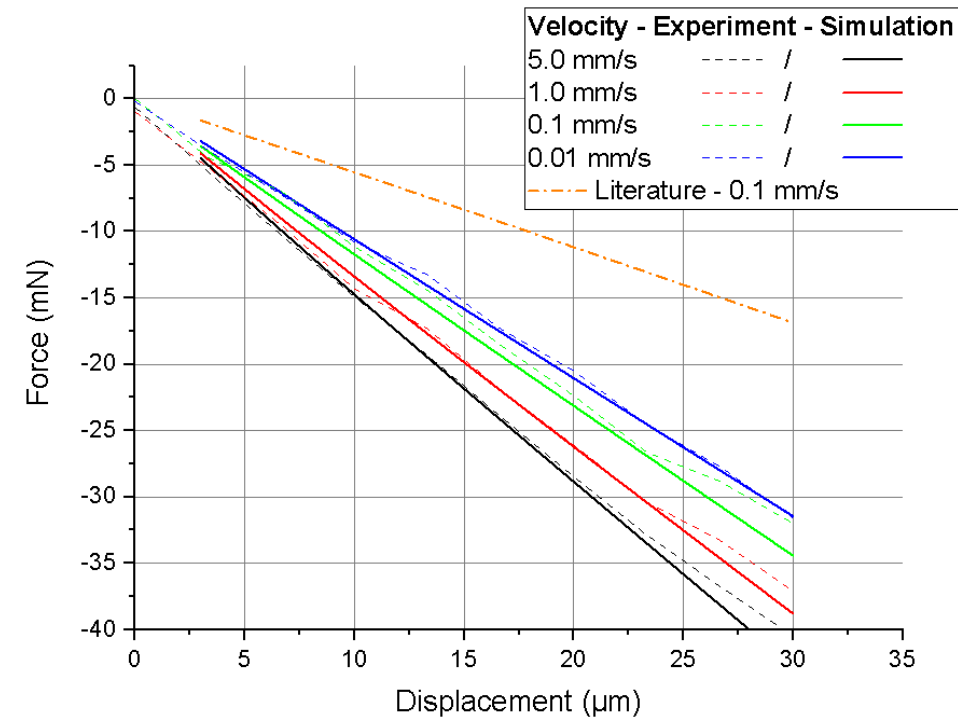
Numerical Validation

Viscoelasticity

- Viscoelasticity using prony series in ANSYS from experimental (DMA) relaxation fit
- Overdrive with different velocities



Time dependent shear relaxation of PDMS

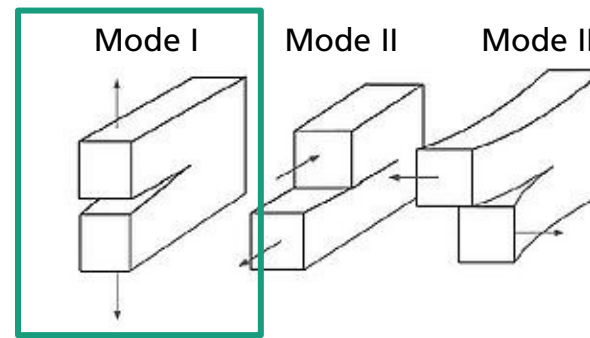


FEA in comparison to the experiment during compression loading

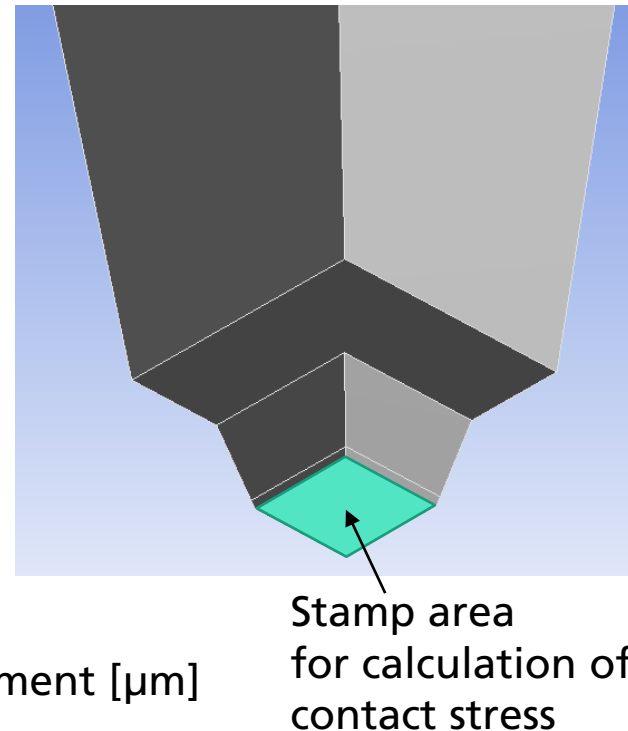
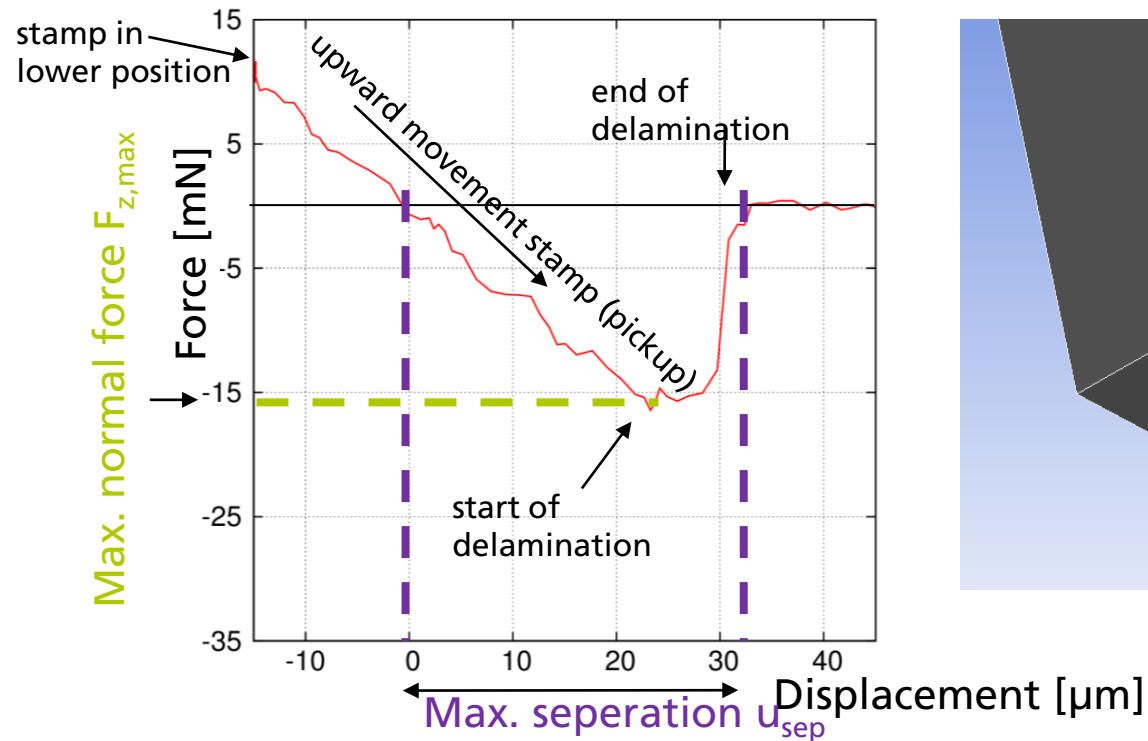
Finite-element-analysis

Numerical Validation

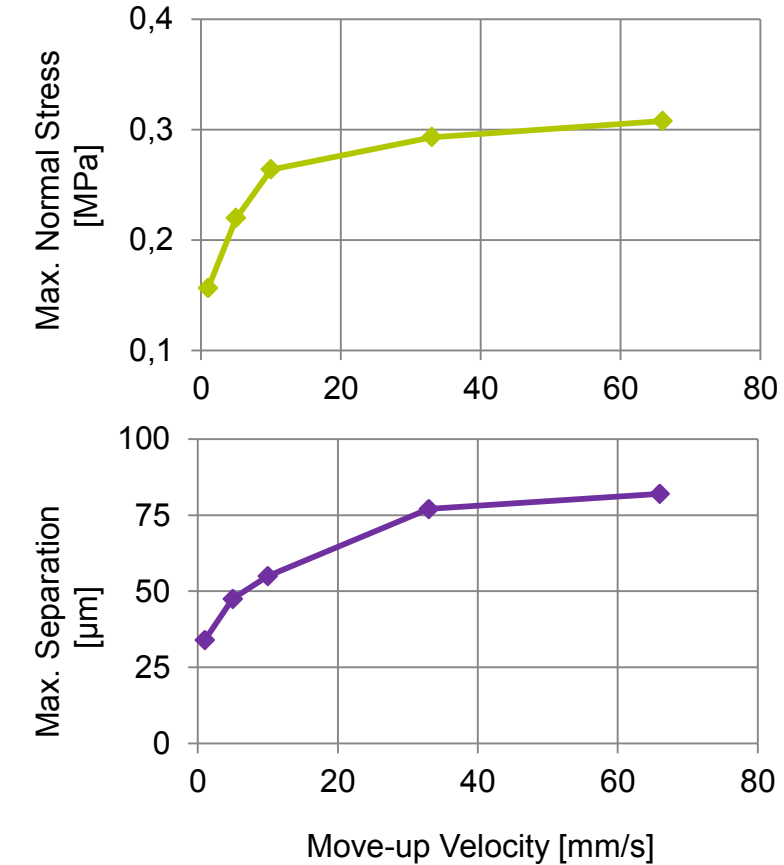
Adhesion



- Cohesive zone modeling (CZM) for adhesion (Mode I)
- How to determine the CZM-parameters from experiment



Resulting CZM-parameters

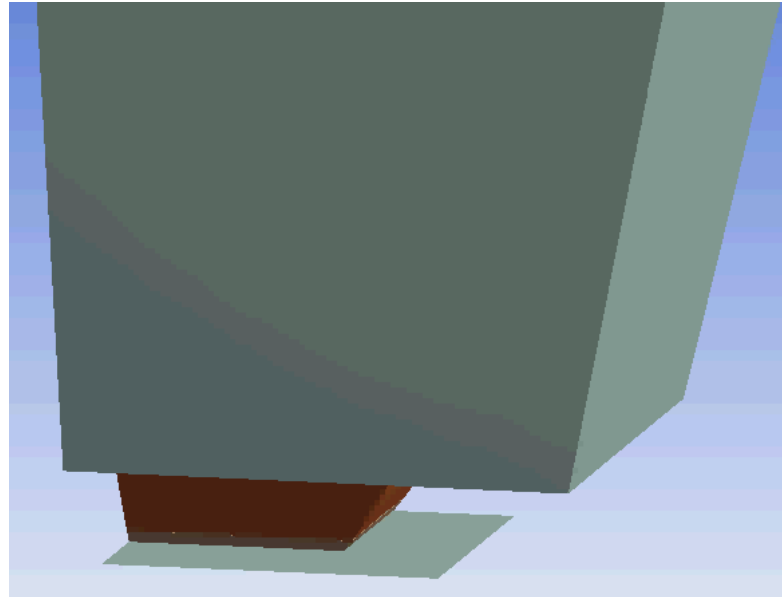


Finite-element-analysis

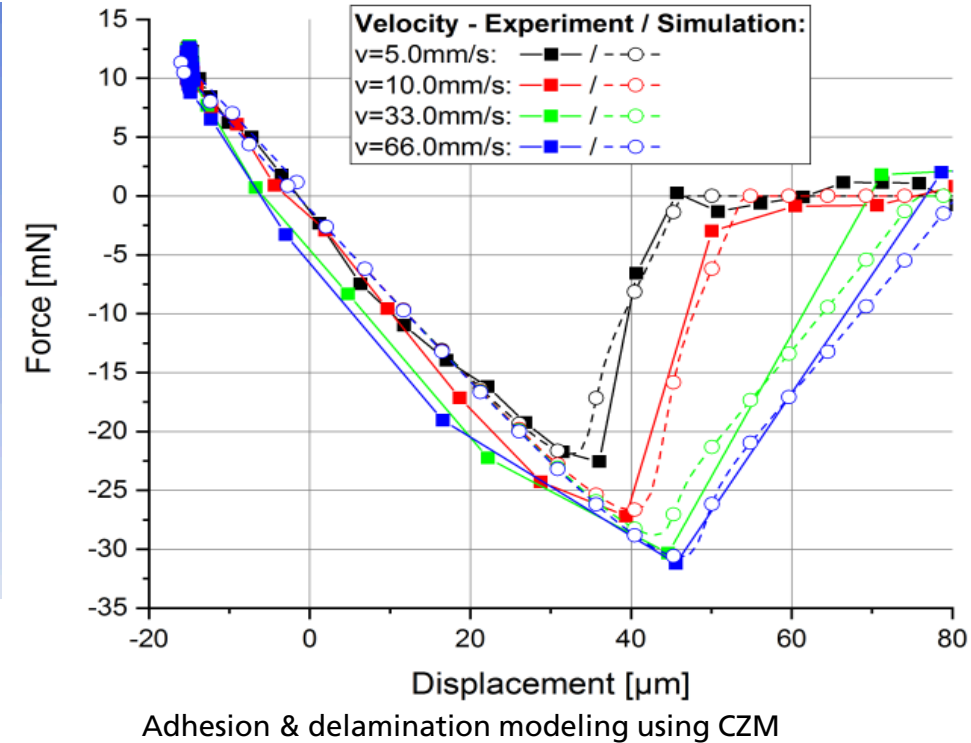
Numerical Validation

Adhesion

- Overdrive speed 0.1mm/s
- Dwell time 1s
- Varying pick-up velocities



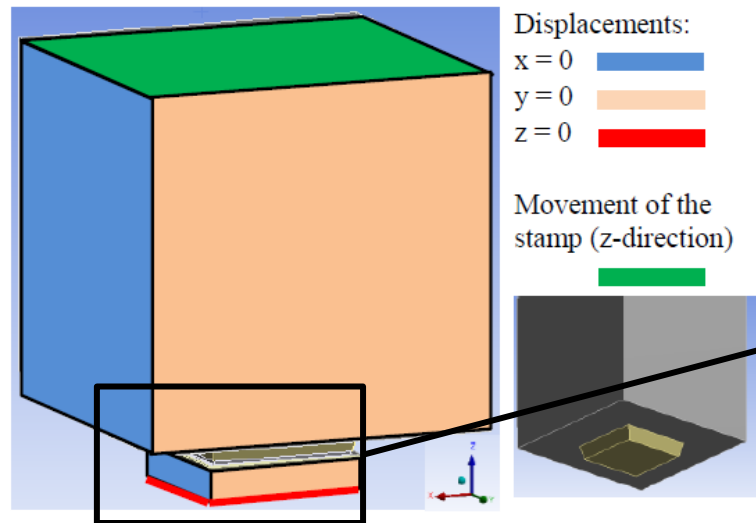
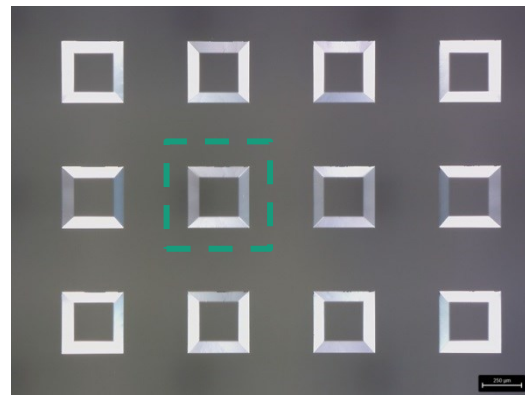
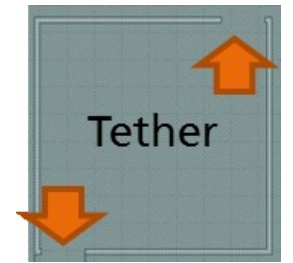
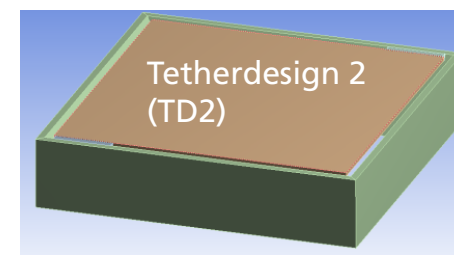
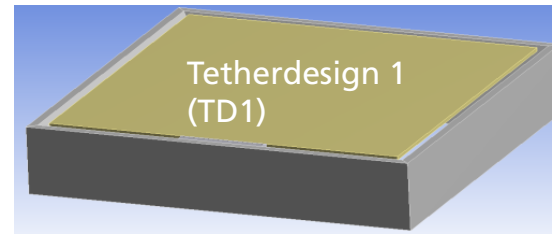
(Slow motion and scaled displacement)



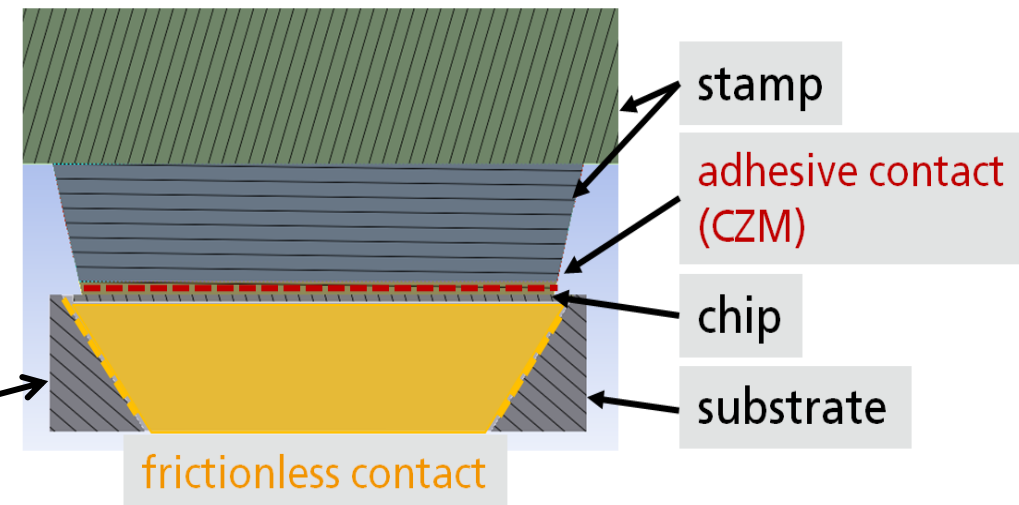
➔ Reaction of the stamp in order to adhesion can be modelled well for different velocities

Finite-element-analysis μ TP-Process Simulation Model Setup

- Single post out of stamp array
- PDMS stamp \rightarrow viscoelastic material model
- Si_3N_4 -structure \rightarrow linear elastic



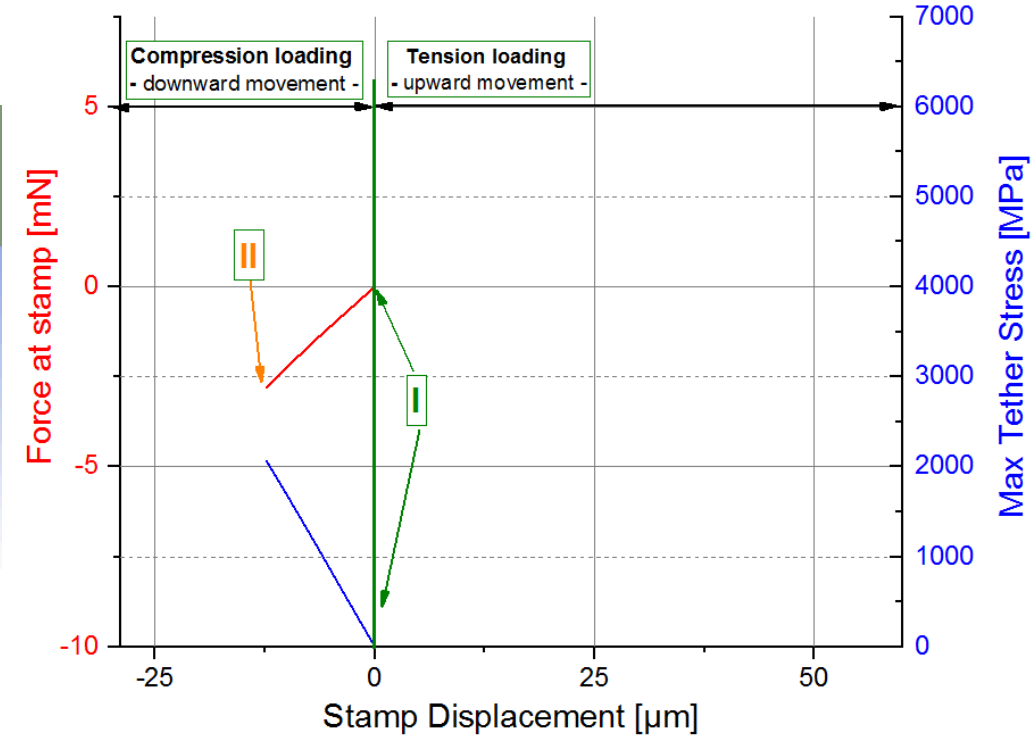
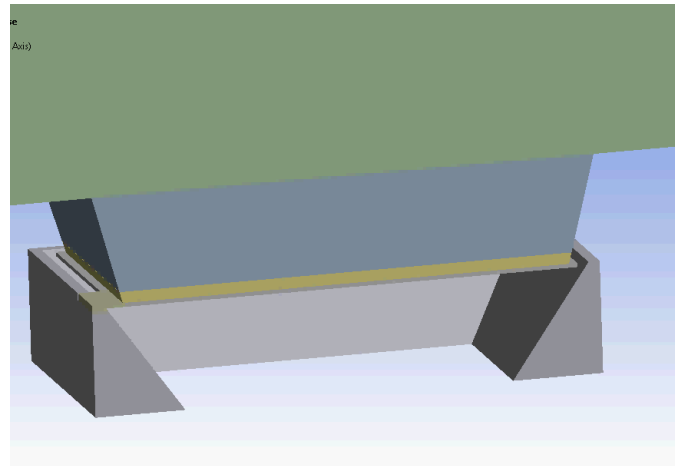
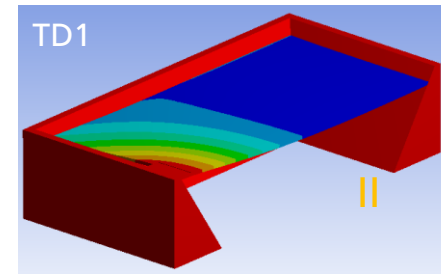
Cross section of the FEA model



Finite-element-analysis μ TP-Process Simulation Kinematic behavior during μ TP (device pick-up)

I – Contact chiplet/PDMS

II – Chiplet contacts remaining source material



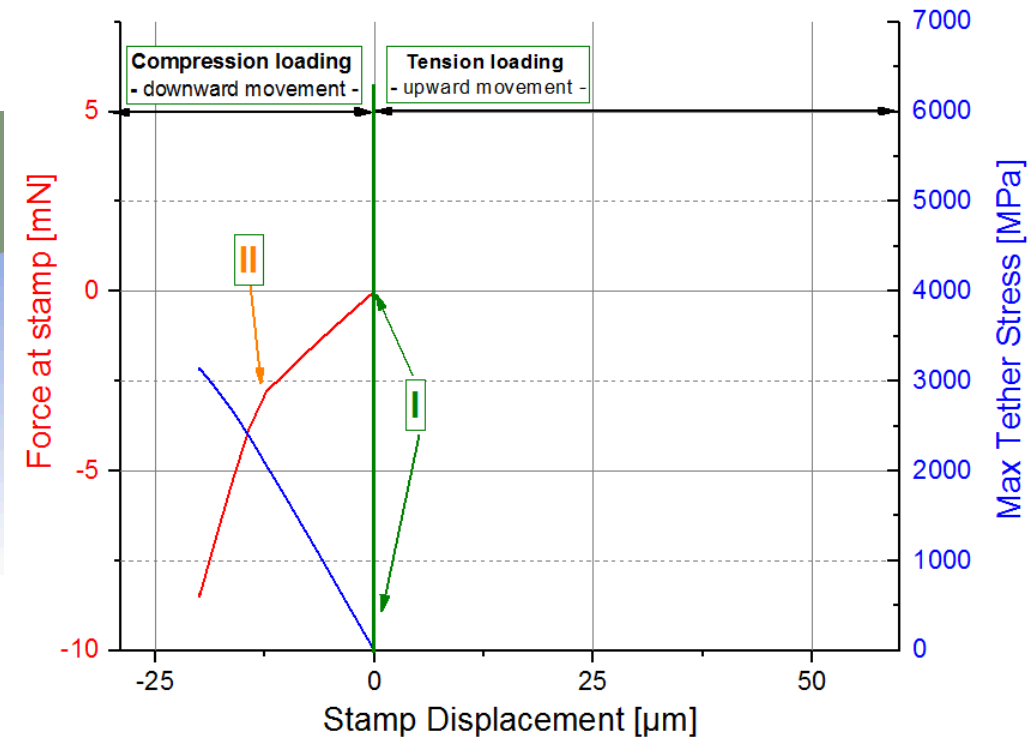
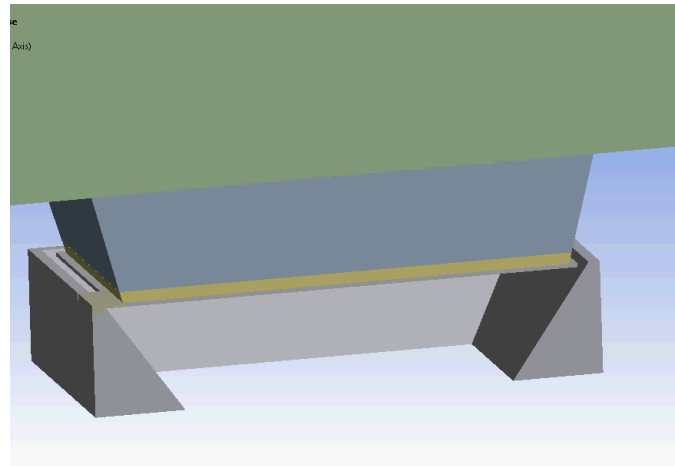
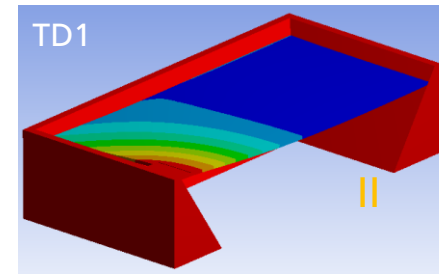
Finite-element-analysis

μ TP-Process Simulation

Kinematic behavior during μ TP (device pick-up)

I – Contact chiplet/PDMS

II – Chiplet contacts remaining source material



Finite-element-analysis

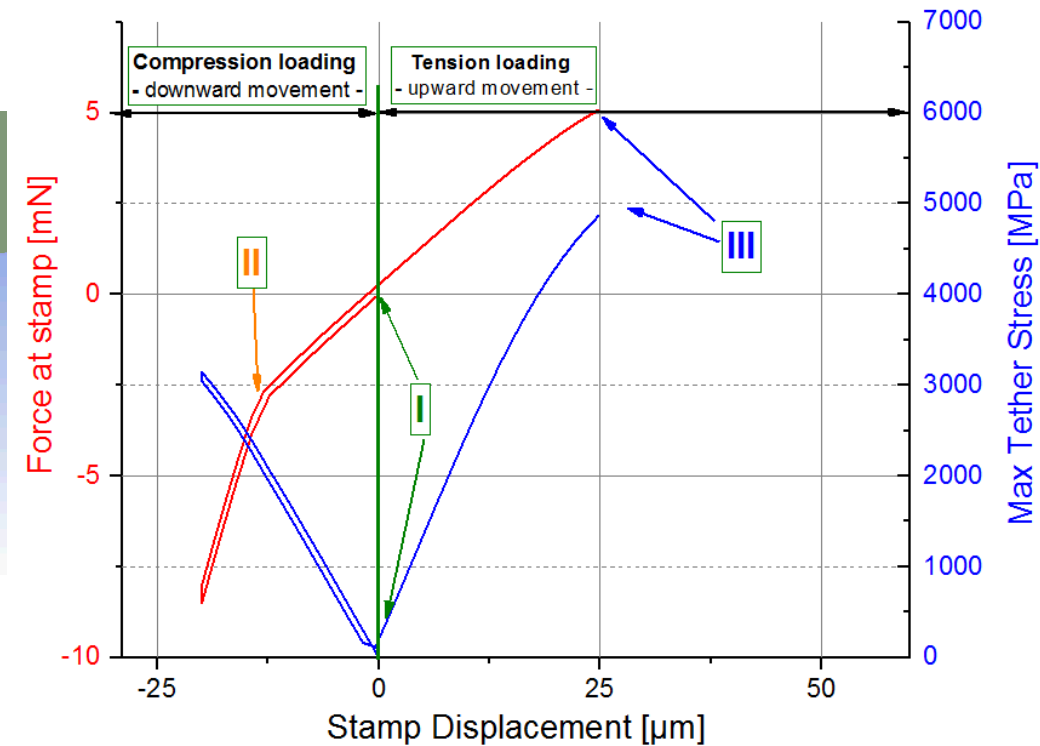
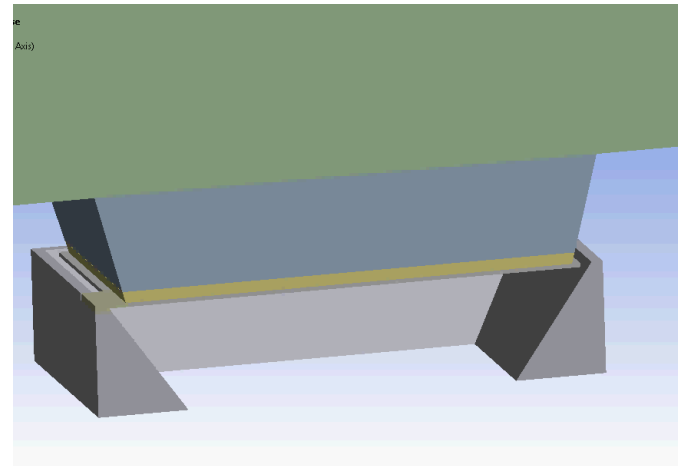
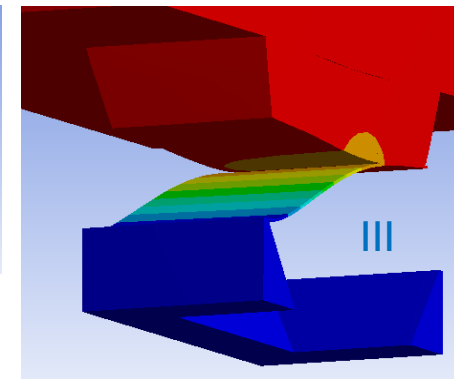
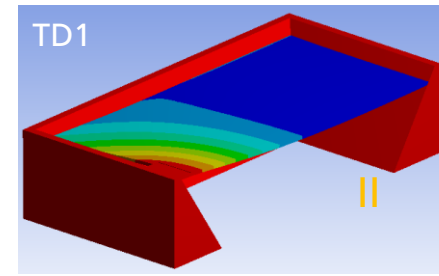
μ TP-Process Simulation

Kinematic behavior during μ TP (device pick-up)

I – Contact chiplet/PDMS

II – Chiplet contacts remaining source material

III – Starting stamp delamination

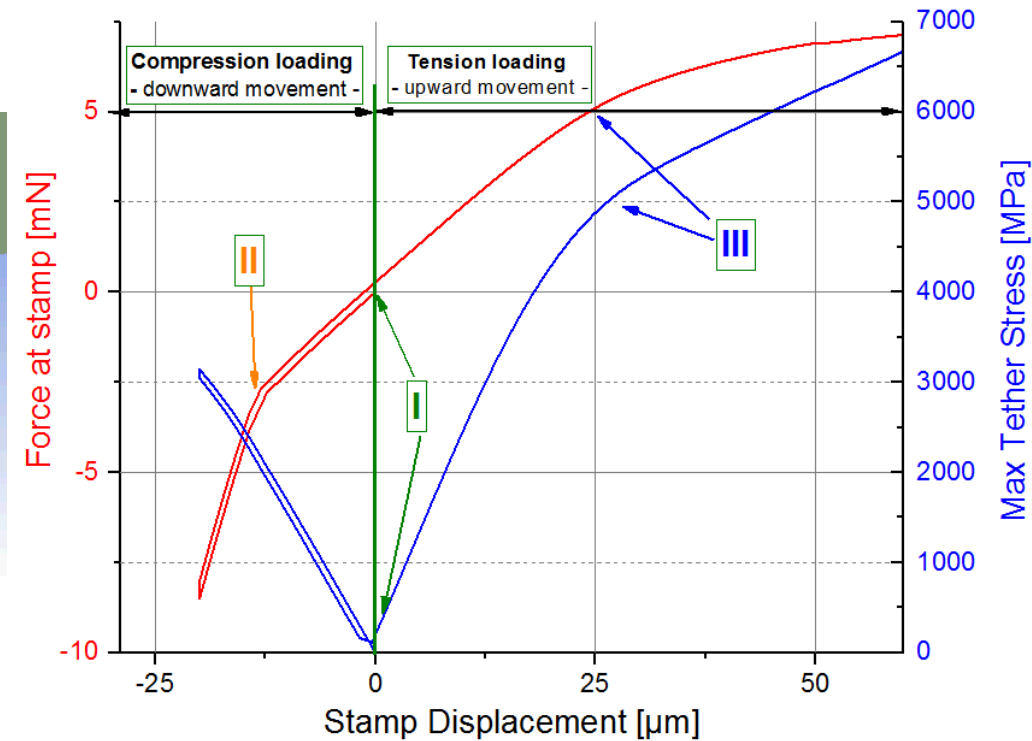
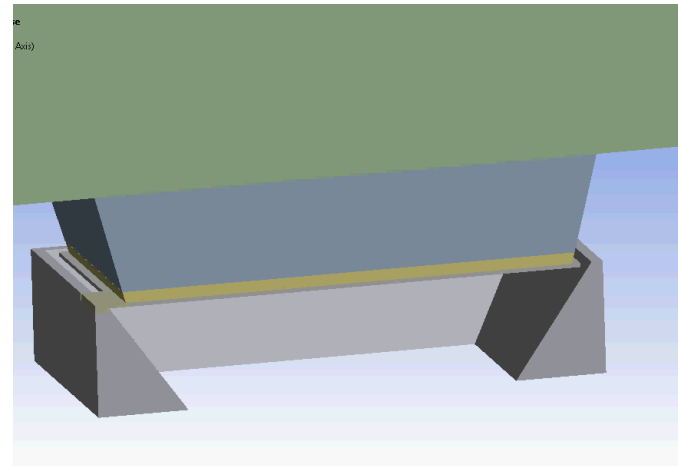
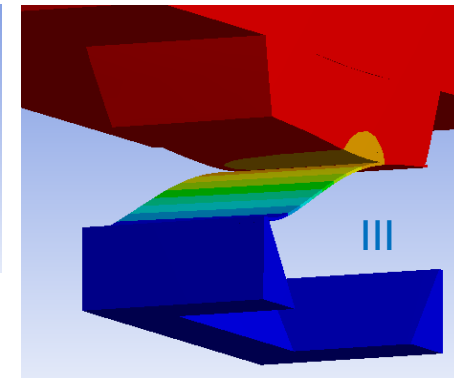
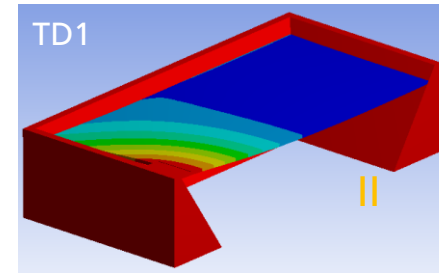


Finite-element-analysis μ TP-Process Simulation Kinematic behavior during μ TP (device pick-up)

I – Contact chiplet/PDMS

II – Chiplet contacts remaining source material

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Finite-element-analysis

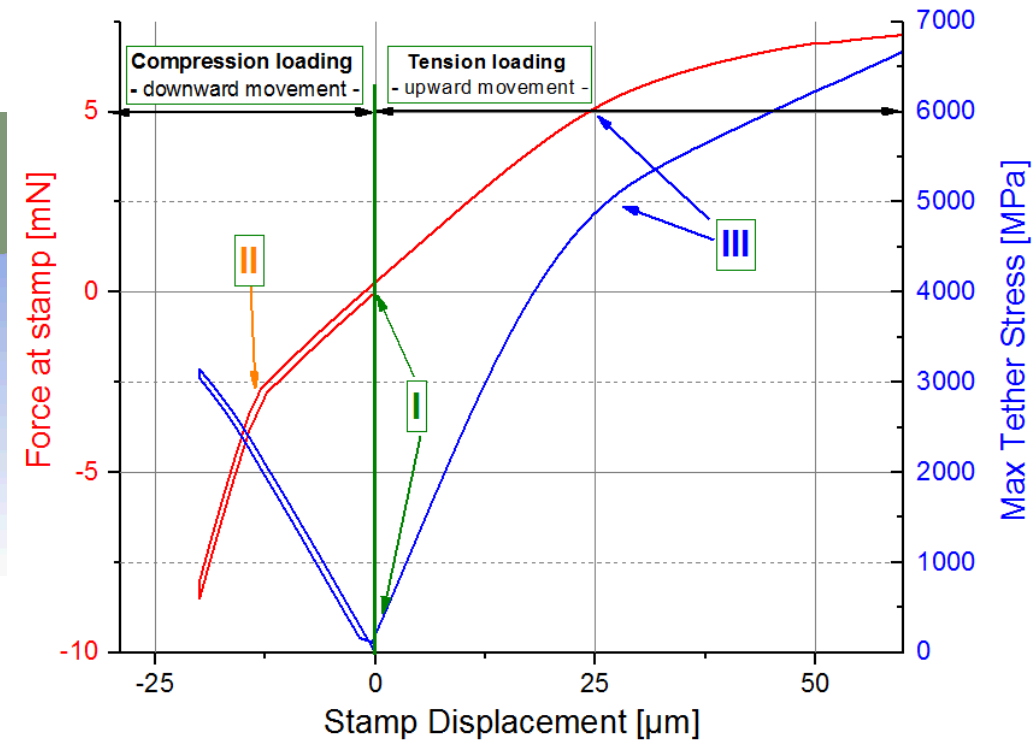
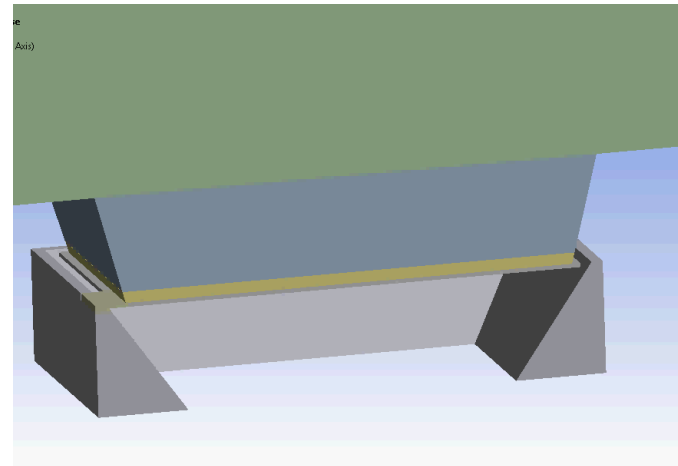
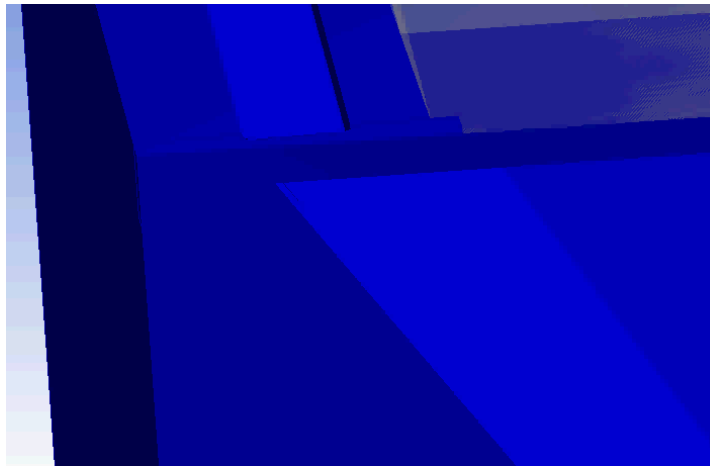
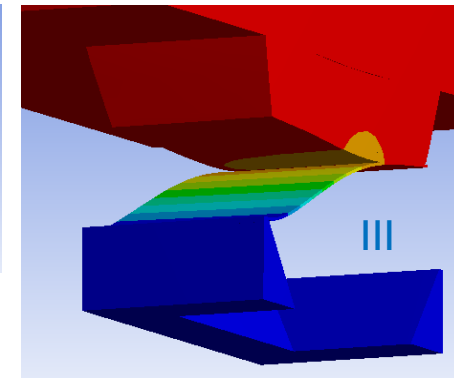
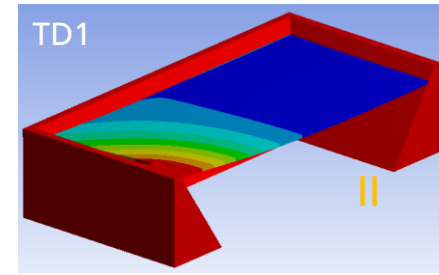
μ TP-Process Simulation

Kinematic behavior during μ TP (device pick-up)

I – Contact chiplet/PDMS

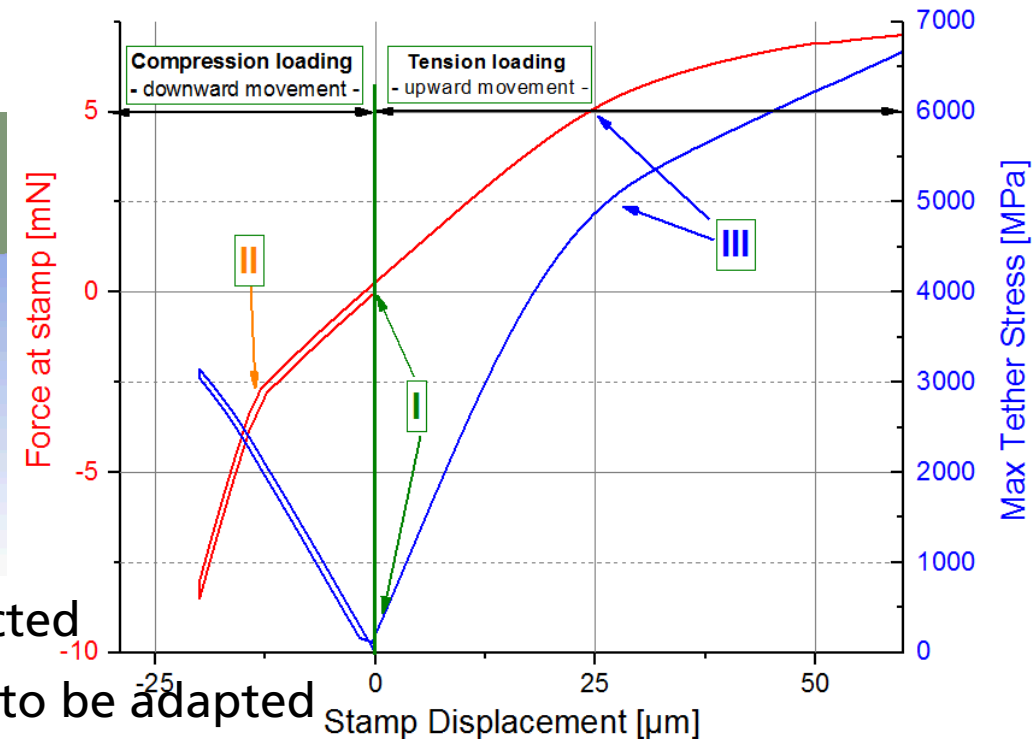
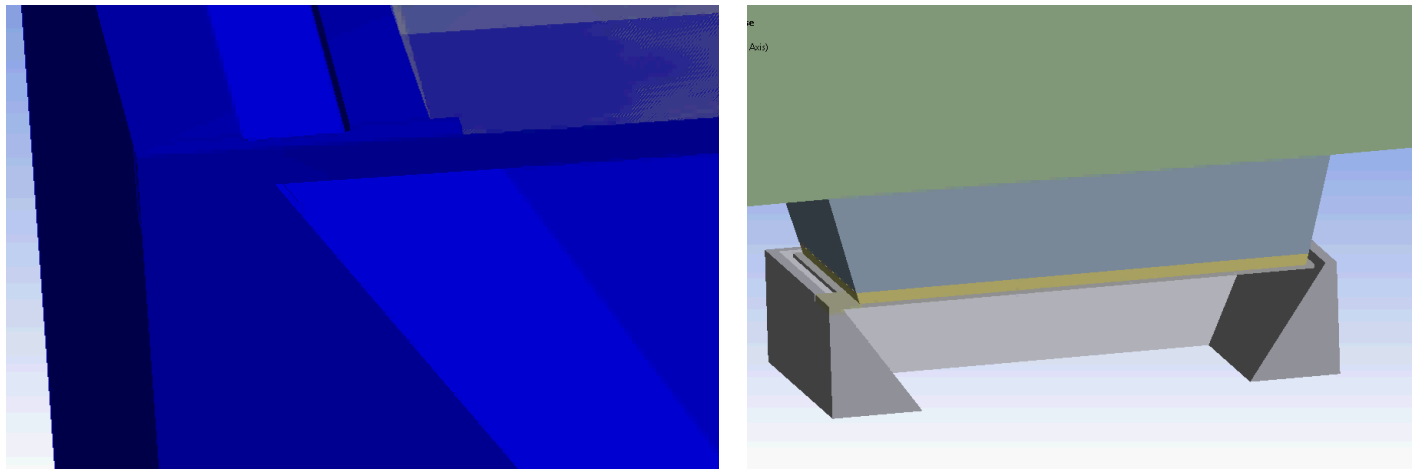
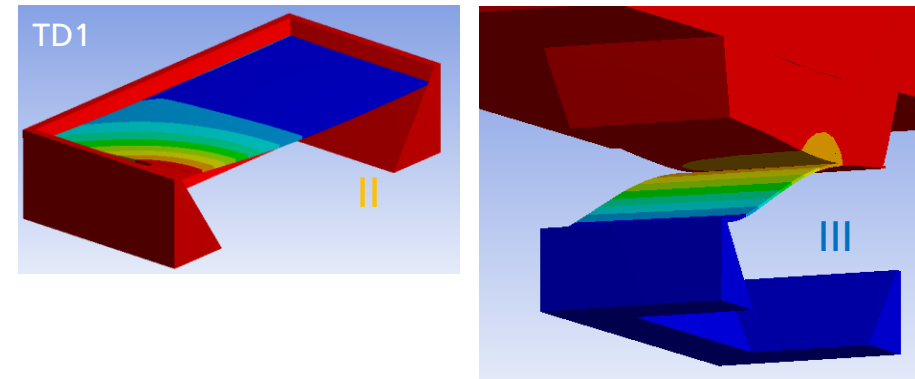
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Finite-element-analysis μ TP-Process Simulation Kinematic behavior during μ TP (device pick-up)

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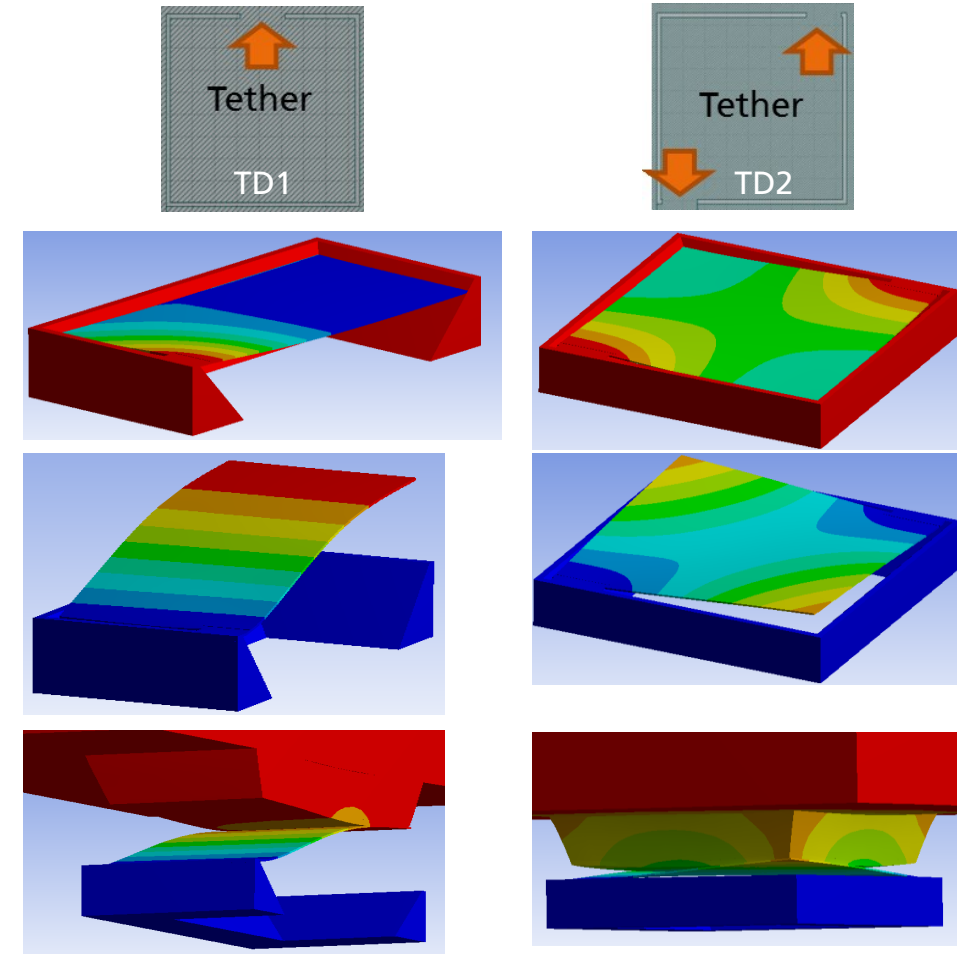
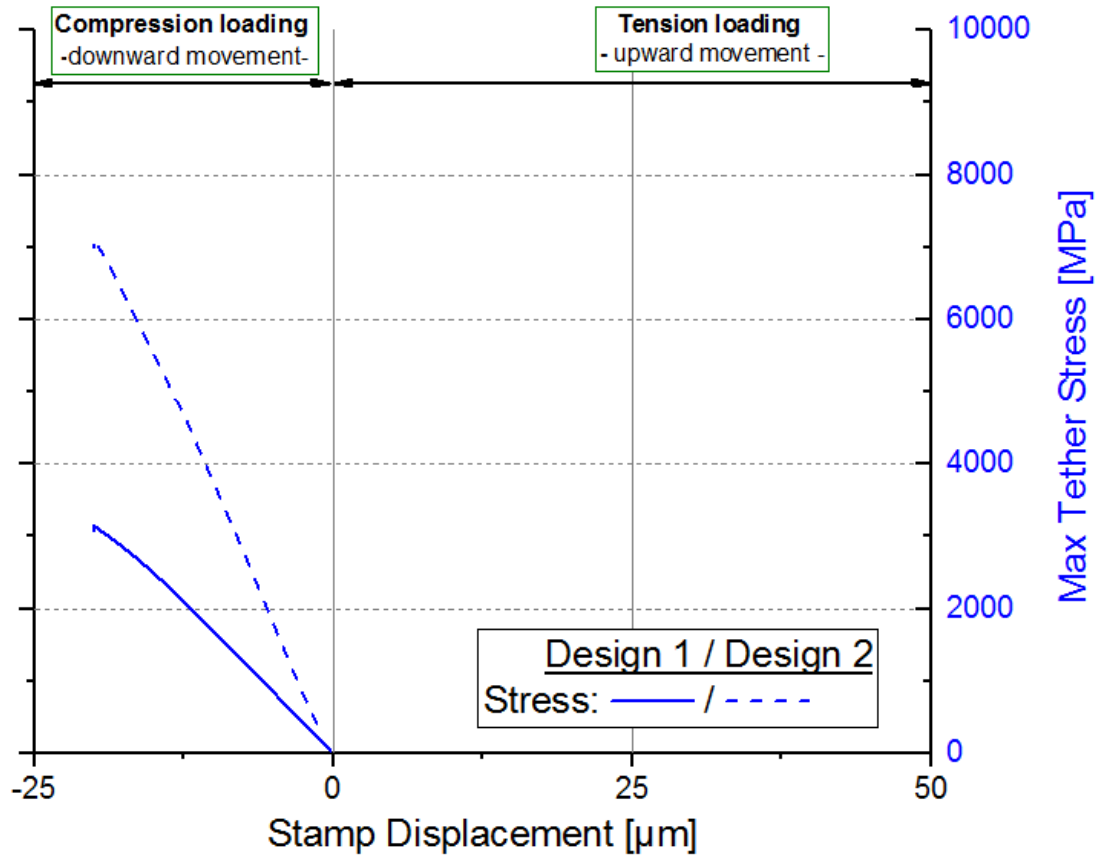


- Critical fracture stress values for Si_3N_4 of 400-500MPa^[1] expected
 → Model assuming a sharp notch, radius and FEA mesh needs to be adapted

Finite-element-analysis

μ TP-Process Simulation

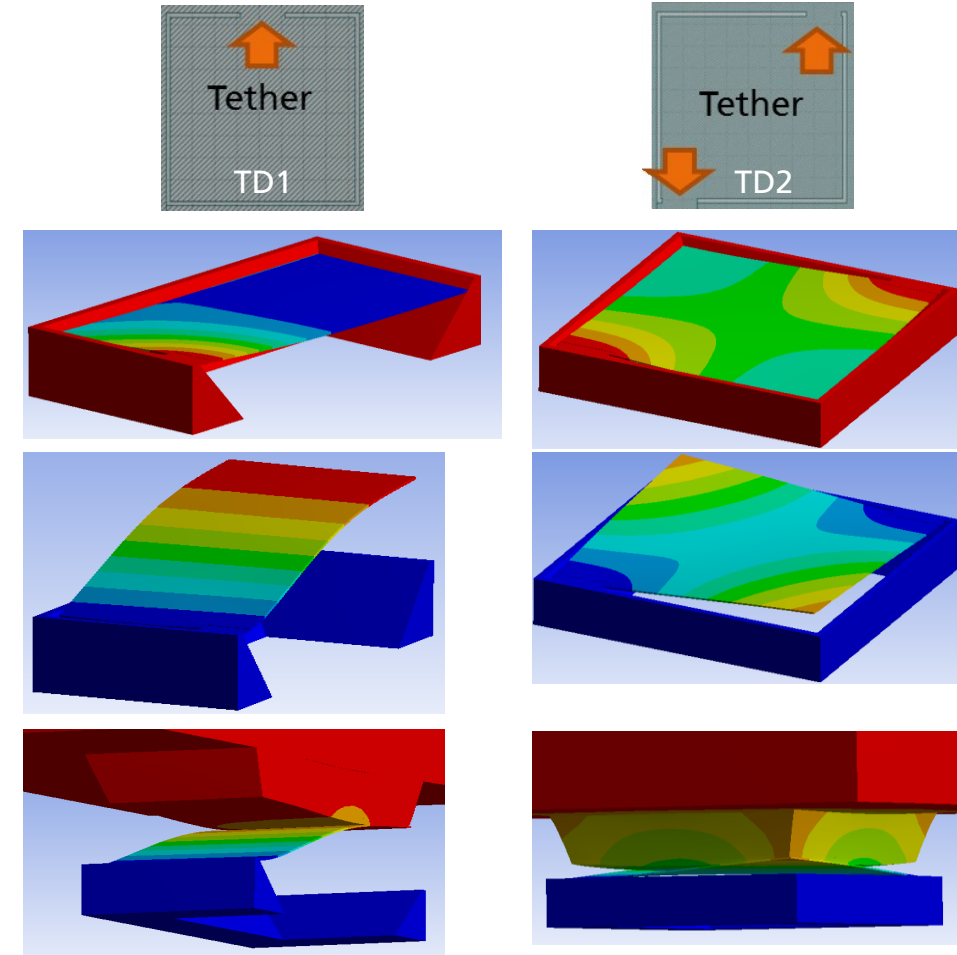
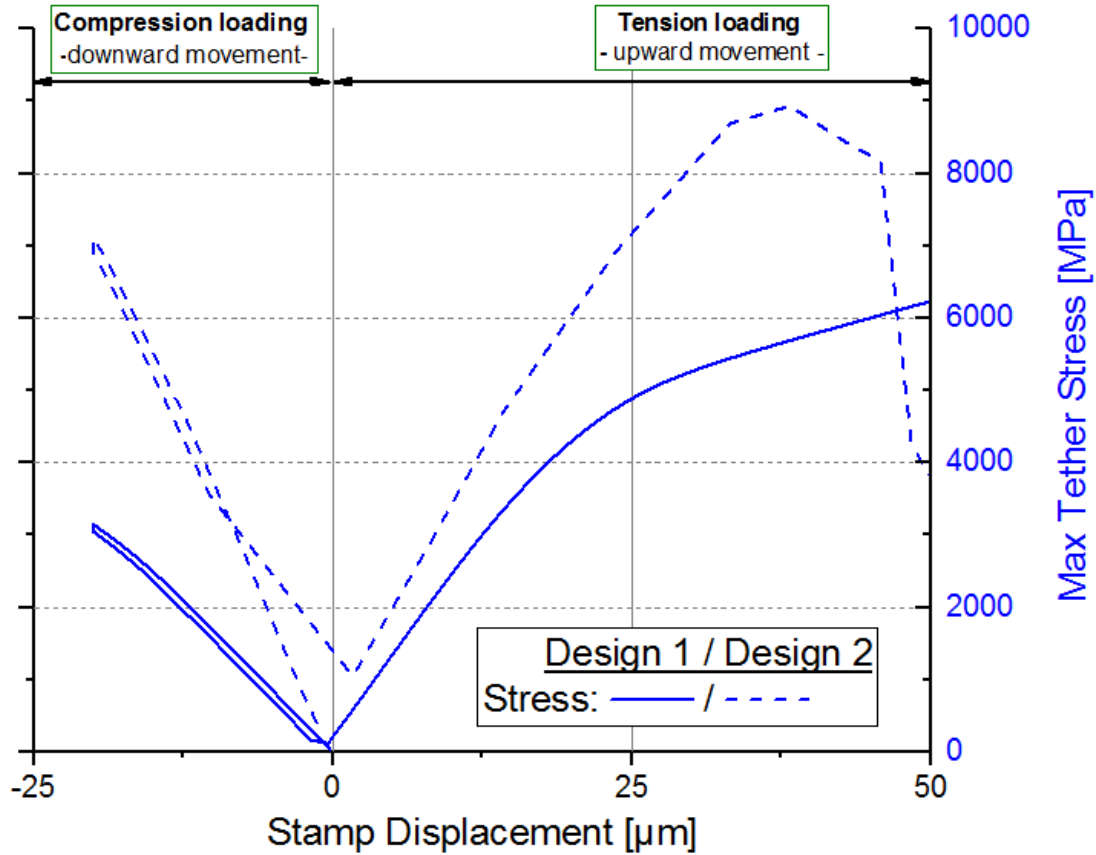
Two different tether designs



Finite-element-analysis

μTP-Process Simulation

Two different tether designs



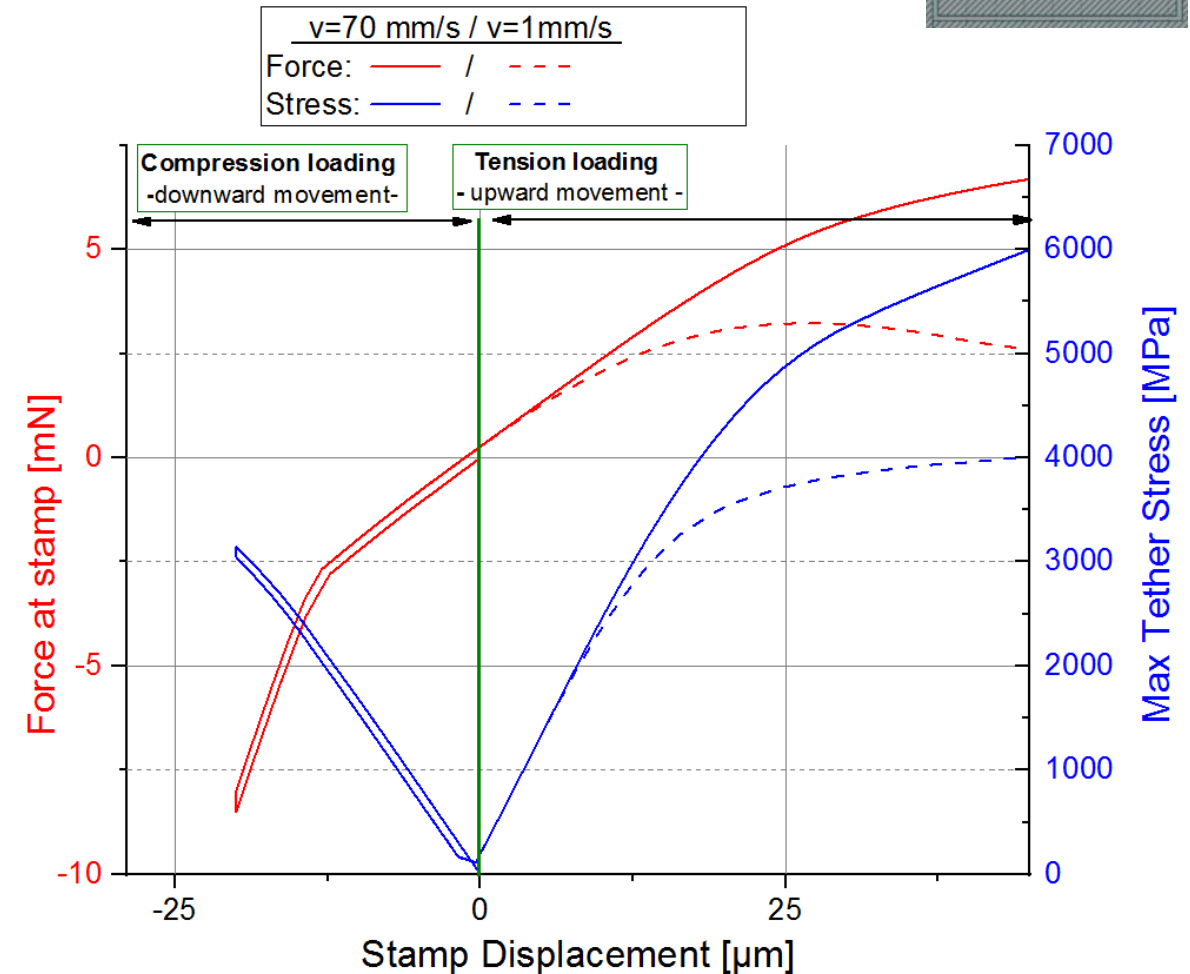
- TD2 stiffer than TD1
 - TD2 increased tether stress at same stamp displacement
- Different tether designs can be analyzed

Finite-element-analysis

μ TP-Process Simulation

Case study: less pick up speed (TD1)

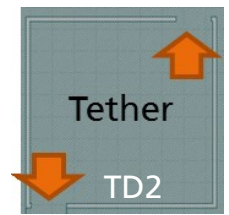
- Delamination occurs at less stamp displacement and a lower forces
- Less tether stress
- Risk of a failing pick up if tether does not break during downward movement



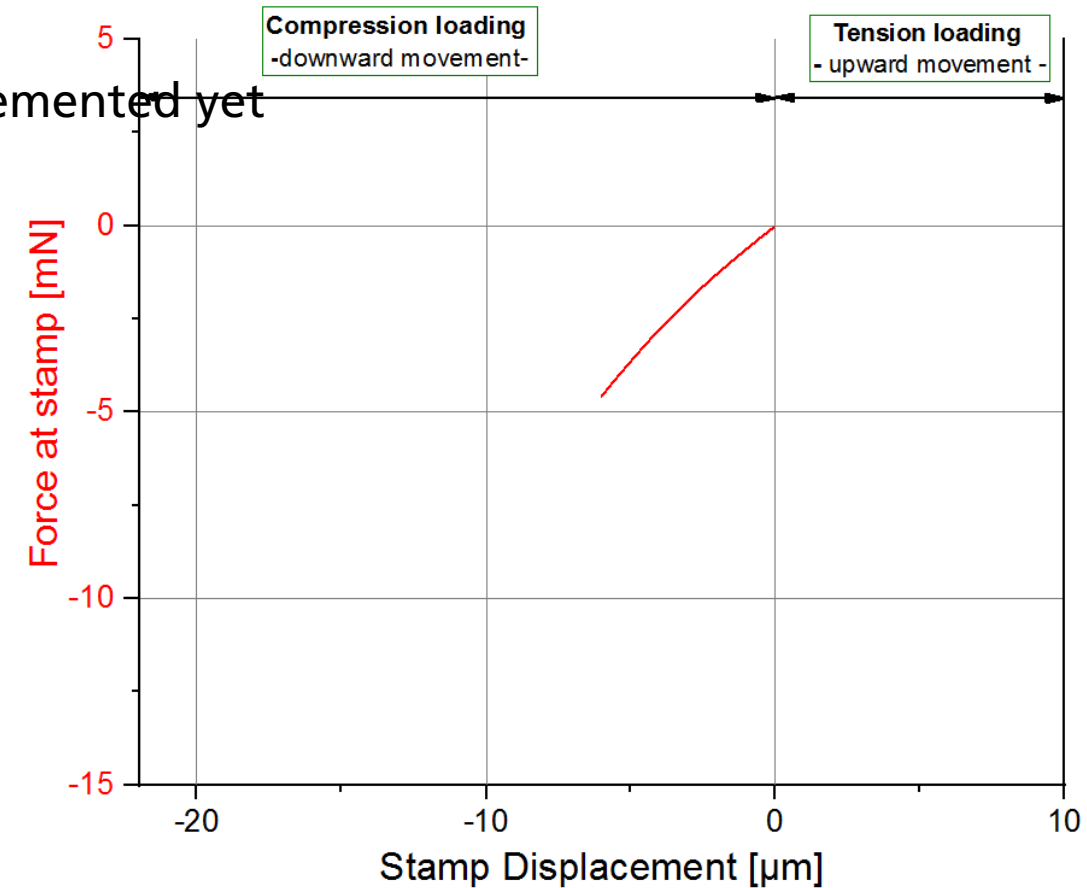
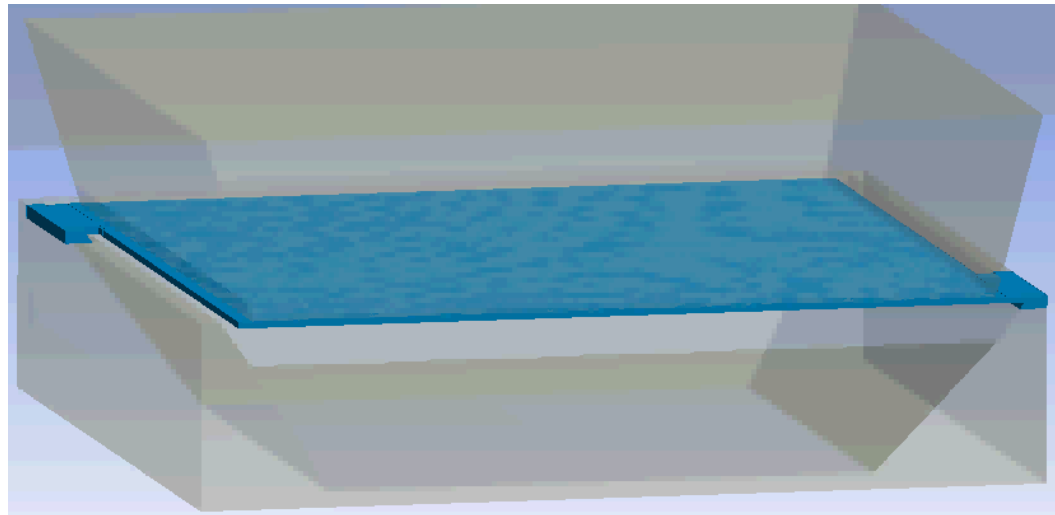
Finite-element-analysis

μ TP-Process Simulation

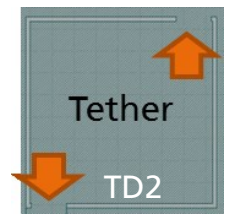
Kinematic behavior of TD2 with breaking tethers



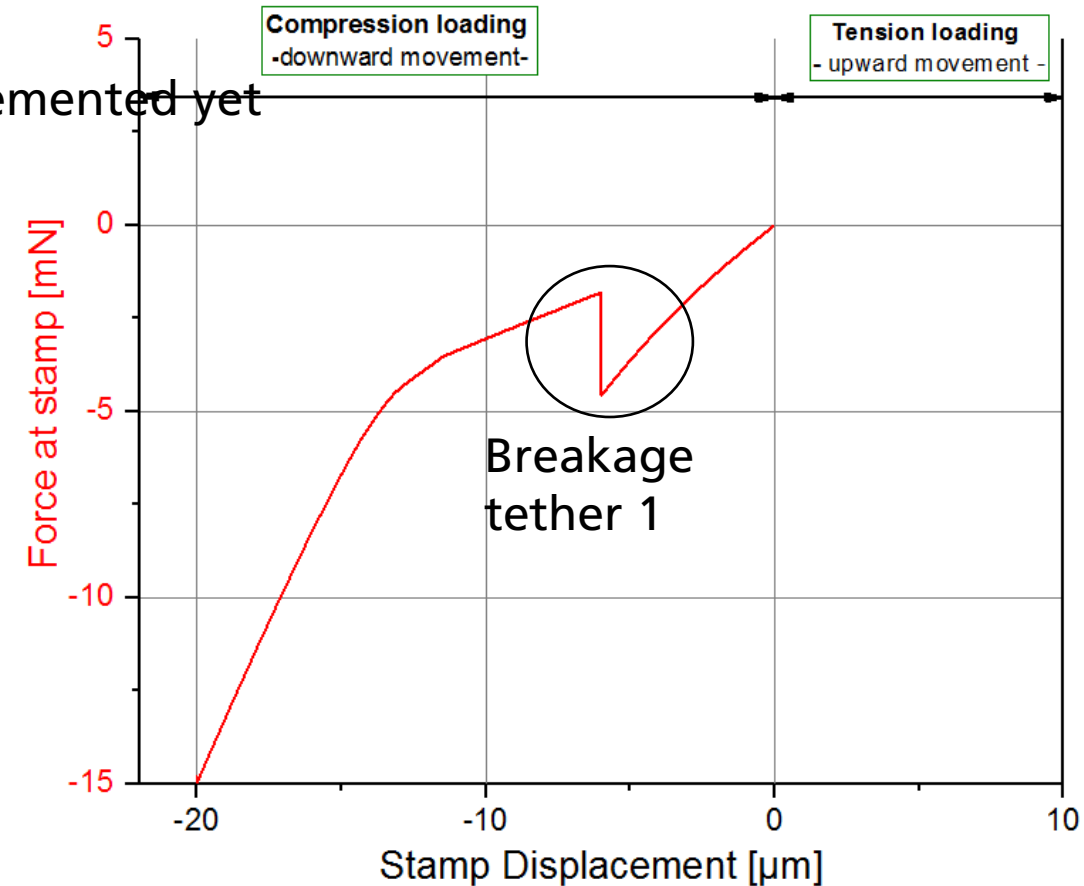
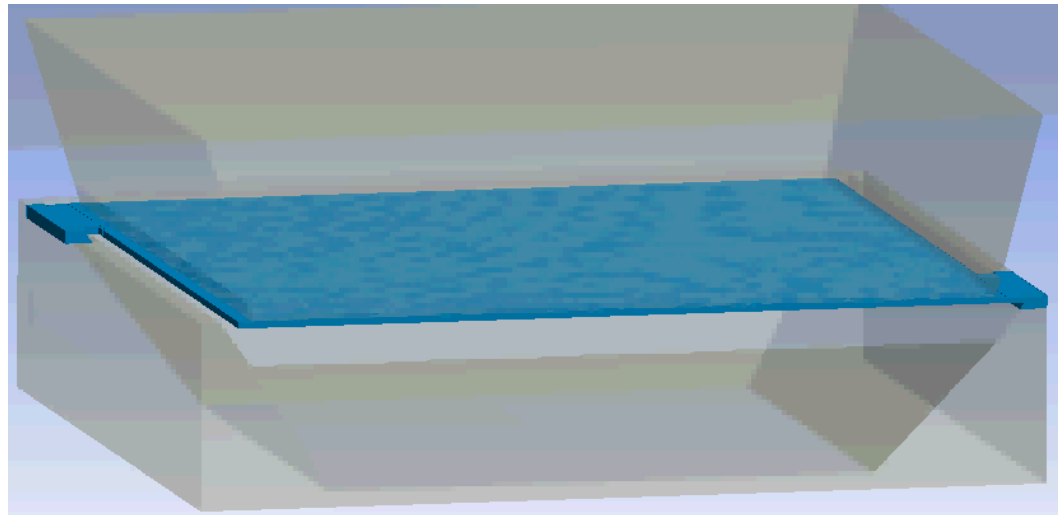
- No fracture mechanical models for tether breakage implemented yet



Finite-element-analysis μTP-Process Simulation Kinematic behavior of TD2 with breaking tethers



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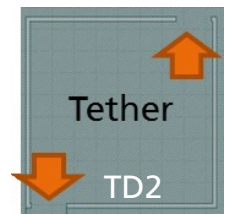


- Tether breakage leads to immediate stamp force and tether stress reduction

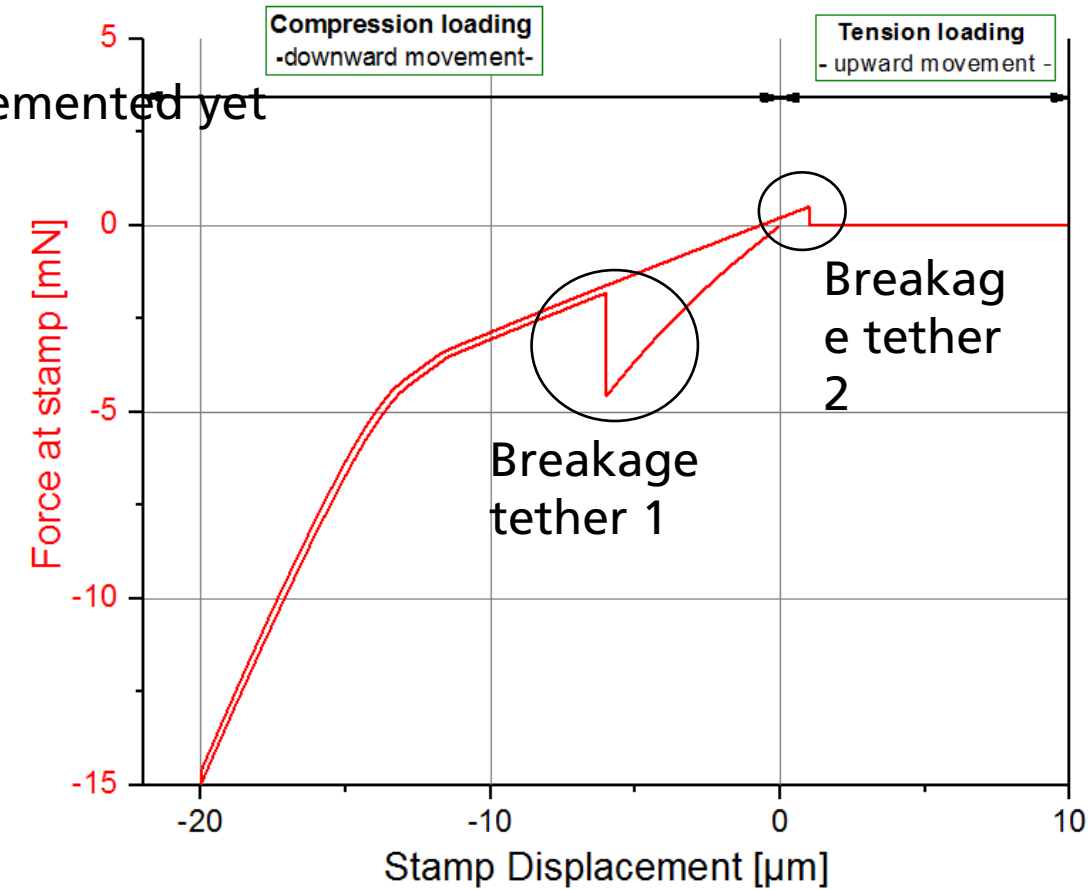
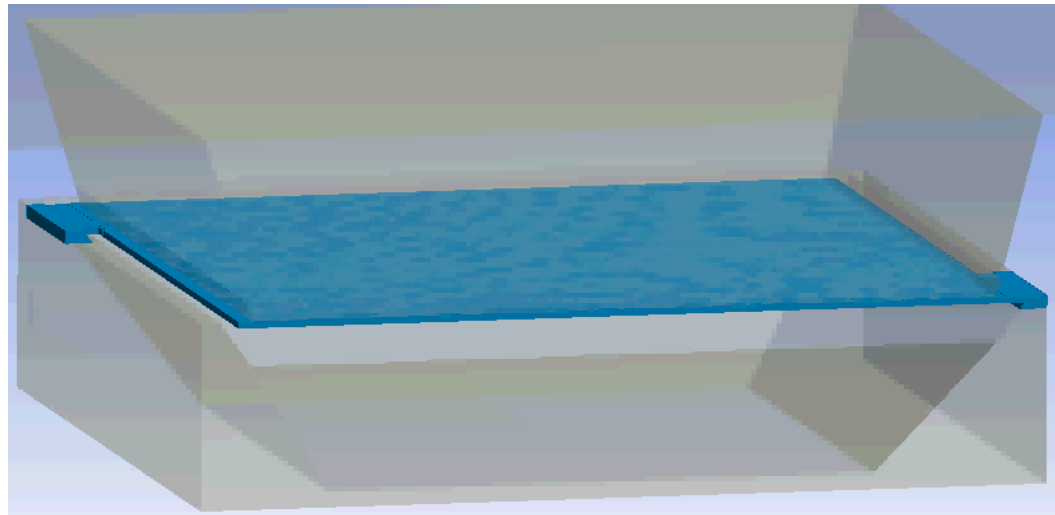
Finite-element-analysis

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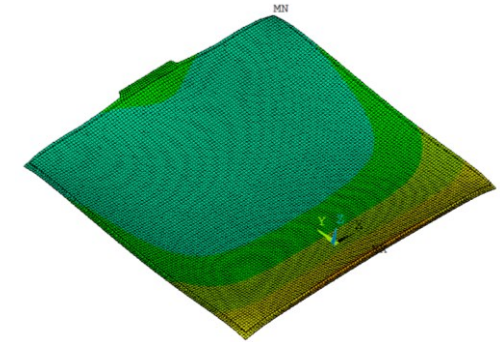
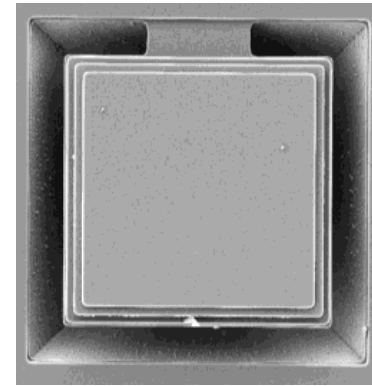
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Summary

- FEA of μ TP inside the „MICROPRINCE“-project for analyzing process reliability
- Mechanical characterization
 - Viscoelastic properties of PDMS by DMA
 - Velocity dependent adhesion measurements on single post stamps
- Process simulation
 - Interaction of stamp and released device regarding stamp and tether stress
 - Tether design and process parameter optimization possible
 - Evaluation of the impact of stamp material

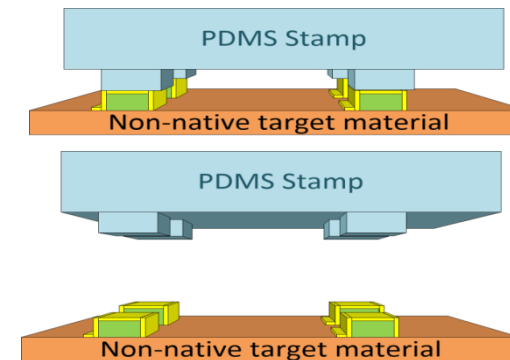
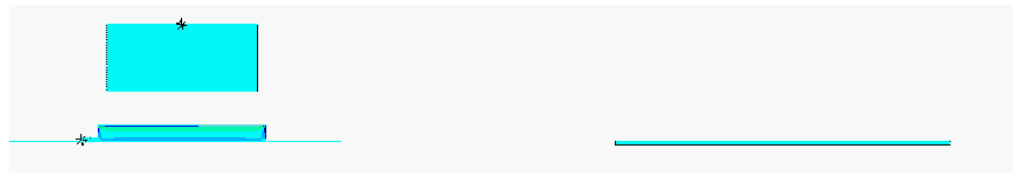
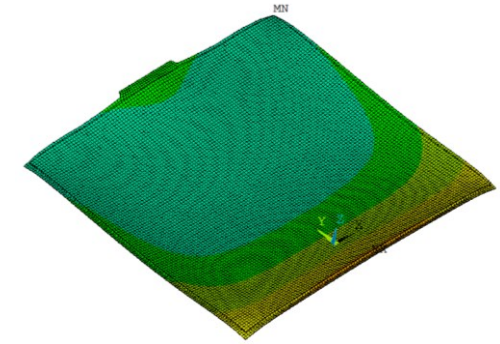
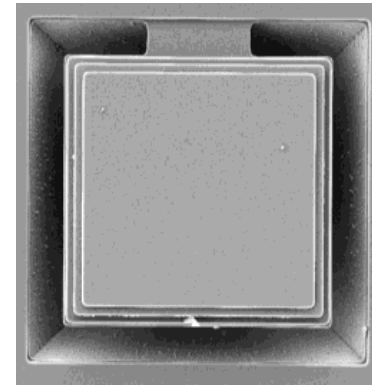
Outlook

- μ TP-process evaluation by single post stamp experiments
- Considering different device designs including intrinsic stresses due to processing
- Evaluation of fracture stress values by nano-indentation experiments
- Including fracture mechanical approaches for tether breakage



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- μ TP-process evaluation by single post stamp experiments
- Considering different device designs including intrinsic stresses due to processing
- Evaluation of fracture stress values by nano-indentation experiments
- Including fracture mechanical approaches for tether breakage
- Model extension to further μ TP process steps



Acknowledgement

The **Microprince** project has received funding from the ECSEL Joint Undertaking under grand agreement No 737465. This Joint Undertaking receives support from the European Union's Horizon 2020 research and innovation programme and Germany, Belgium, Ireland.

